

MOS INTEGRATED LO IR GUIT μ PD78P4038

16/8-BIT SINGLE-CHIP MICROCONTROLLER

The μ PD78P4038, 78K/IV Series' product, is a one-time PROM or EPROM version of the μ PD784035, μ PD784036, μ PD784037, and μ PD784038 with internal masked ROM.

Since user programs can be written to PROM, this microcontroller is best suited for evaluation in system development, manufacture of small quantities of multiple products, and fast start-up of applications.

For specific functions and other detailed information, consult the following user's manual. This manual is required reading for design work.

> μ PD784038, 784038Y Subseries User's Manual, Hardware : U11316E 78K/IV Series User's Manual, Instruction : U10905E

FEATURES

- Compatible with the μ PD78P238, μ PD78P4026, and μ PD78P4038Y
- Internal PROM: 128 Kbytes
 - μPD78P4038KK-T : EPROM (best suited for system evaluation)
 - μPD78P4038GC-3B9 : One-time PROM (best suited for manufacture of small quantities) μPD78P4038GC-8BT : One-time PROM (best suited for manufacture of small quantities) μ PD78P4038GK-BE9 : One-time PROM (best suited for manufacture of small quantities)
- Internal RAM : 4,352 bytes
- Power supply voltage: VDD = 2.7 to 5.5 V
- QTOPTM microcomputer (In the planning phase)

Remark The QTOP microcomputer is a microcomputer with a built-in one-time PROM that is totally supported by NEC. The support includes writing application programs, marking, screening, and verification.

ORDERING INFORMATION

| | Part number | Package | Internal ROM |
|---|---|--|------------------------------------|
| | μPD78P4038GC-3B9 | 80-pin plastic QFP (14 \times 14 \times 2.7 mm) | One-time PROM |
| * | μ PD78P4038GC- \times \times -3B9 | 80-pin plastic QFP (14 \times 14 \times 2.7 mm) | One-time PROM (QTOP microcomputer) |
| | μ PD78P4038GC-8BT | 80-pin plastic QFP (14 \times 14 \times 1.4 mm) | One-time PROM |
| | μ PD78P4038GK-BE9 | 80-pin plastic TQFP (fine pitch) (12 \times 12 mm) | One-time PROM |
| * | μ PD78P4038GK- \times \times -BE9 | 80-pin plastic TQFP (fine pitch) (12 \times 12 mm) | One-time PROM (QTOP microcomputer) |
| | μ PD78P4038KK-T | 80-pin ceramic WQFN (14 × 14 mm) | EPROM |

In this reference, all ROM components that are common to one-time PROM and EPROM are referred to as PROM.

The information in this document is subject to change without notice.

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QUALITY GRADE

| | Part number | Package | Quality grade |
|---|--|--|---|
| | μPD78P4038GC-3B9 | 80-pin plastic QFP (14 \times 14 \times 2.7 mm) | Standard (for general electronic equipment) |
| * | μ PD78P4038GC- $\times\times$ -3B9 | 80-pin plastic QFP (14 \times 14 \times 2.7 mm) | Standard (for general electronic equipment) |
| | μ PD78P4038GC-8BT | 80-pin plastic QFP (14 \times 14 \times 1.4 mm) | Standard (for general electronic equipment) |
| | μ PD78P4038GK-BE9 | 80-pin plastic TQFP (fine pitch) (12 \times 12 mm) | Standard (for general electronic equipment) |
| * | μ PD78P4038GK- $\times\times$ -BE9 | 80-pin plastic TQFP (fine pitch) (12 \times 12 mm) | Standard (for general electronic equipment) |
| | μ PD78P4038KK-T | 80-pin ceramic WQFN (14 \times 14 mm) | Not applied (for function evaluation) |

Please refer to "Quality Grades on NEC Semiconductor Devices" (Document No. C11531E) published by NEC Corporation to know the specification of quality grade on the devices and its recommended applications.

Caution The EPROM versions of the μ PD78P4038 are not intended for use in mass-produced products; they do not have reliability high enough for such purposes. Their use should be restricted to functional evaluation in experiment or trial manufacture.

Remark xxx indicates ROM code suffix.

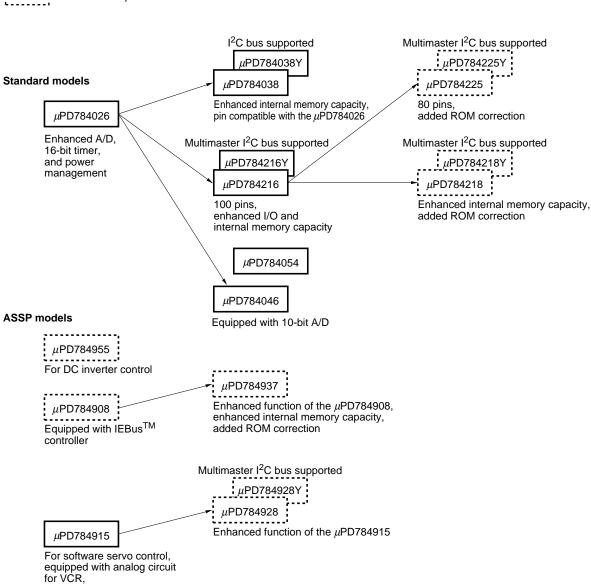
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78K/IV SERIES PRODUCT DEVELOPMENT DIAGRAM

: Under mass production

enhanced timer



FUNCTIONS

(1/2)

| Item | | Functions | | | | | |
|--|--------------------------------|--|--|---|--|--|--|
| Number of basic instructions (mnemonics) | | 113 | | | | | |
| General-purpos | se register | 8 bits × 16 regist | ters \times 8 banks, or 16 bits \times 8 regis | sters × 8 banks (memory mapping) | | | |
| Minimum instruexecution time | ıction | 125 ns/250 ns/50 | 00 ns/1,000 ns (at 32 MHz) | | | | |
| Internal | PROM | 128 Kbytes (Can | 128 Kbytes (Can be changed to 48 K, 64 K, or 96 Kbytes by software) | | | | |
| memory | RAM | 4,352 bytes (Can be changed to 2,048 or 3,584 bytes by software) | | | | | |
| Memory space | | Program and dat | a: 1 Mbyte | | | | |
| I/O ports | Total | 64 | | | | | |
| | Input | 8 | | | | | |
| | Input/output | 56 | | | | | |
| Additional function | Pins with pull- up resistor | 54 | | | | | |
| pins Note | LED direct drive outputs | 24 | | | | | |
| | Transistor direct drive | 8 | | | | | |
| Real-time outp | ut ports | 4 bits \times 2, or 8 bits \times 1 | | | | | |
| Timer/counter | | Timer/counter 0: (16 bits) | Timer register \times 1 Capture register \times 1 Compare register \times 2 | Pulse output capability Toggle output PWM/PPG output One-shot pulse output | | | |
| | | Timer/counter 1: (8/16 bits) | Timer register \times 1 Capture register \times 1 Capture/compare register \times 1 Compare register \times 1 | Pulse output capability • Real-time output (4 bits × 2) | | | |
| | | Timer/counter 2: (8/16 bits) | Timer register \times 1 Capture register \times 1 Capture/compare register \times 1 Compare register \times 1 | Pulse output capability | | | |
| | | Timer 3 : (8/16 bits) | Timer register × 1 Compare register × 1 | | | | |
| PWM outputs | | 12-bit resolution × 2 channels | | | | | |
| Serial interface | | UART/IOE (3-wire serial I/O): 2 channels (incorporating baud rate generator) CSI (3-wire serial I/O, 2-wire serial I/O): 1 channel | | | | | |
| A/D converter | | 8-bit resolution × | 8 channels | | | | |
| D/A converter | | 8-bit resolution × | 2 channels | | | | |

Note Additional function pins are included in the I/O pins.

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(2/2)

| Item | | Functions | | | |
|----------------|-----------------|---|--|--|--|
| Clock output | | Selected from fclk, fclk/2, fclk/4, fclk/8, or fclk/16 (can be used as a 1-bit output port) | | | |
| Watchdog timer | | 1 channel | | | |
| Standby | | HALT/STOP/IDLE mode | | | |
| Interrupt | Hardware source | 23 (16 internal, 7 external (sampling clock variable input: 1)) | | | |
| | Software source | BRK instruction, BRKCS instruction, operand error | | | |
| | Nonmaskable | 1 internal, 1 external | | | |
| | Maskable | 15 internal, 6 external | | | |
| | | 4-level programmable priority 3 operation statuses: vectored interrupt, macro service, context switching | | | |
| Supply volt | age | V _{DD} = 2.7 to 5.5 V | | | |
| Package | | 80-pin plastic QFP ($14 \times 14 \times 2.7 \text{ mm}$) 80-pin plastic QFP ($14 \times 14 \times 1.4 \text{ mm}$) 80-pin plastic TQFP (fine pitch) ($12 \times 12 \text{ mm}$) 80-pin ceramic WQFN ($14 \times 14 \text{ mm}$) | | | |

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1. DIFFERENCES BETWEEN μ PD78P4038 AND MASKED ROM PRODUCTS

The μ PD78P4038 is produced by replacing the masked ROM in the μ PD784035, μ PD784036, μ PD784037, or μ PD784038 with PROM to which data can be written. The functions of the μ PD78P4038 are the same as those of the μ PD784035, μ PD784036, μ PD784037, or μ PD784038 except for the PROM specification such as writing and verification, except that the PROM size can be changed to 48 K, 64 K, or 96 Kbytes, and except that the internal RAM size can be changed to 2,048 or 3,584 bytes.

Table 1-1 shows the differences between these products.

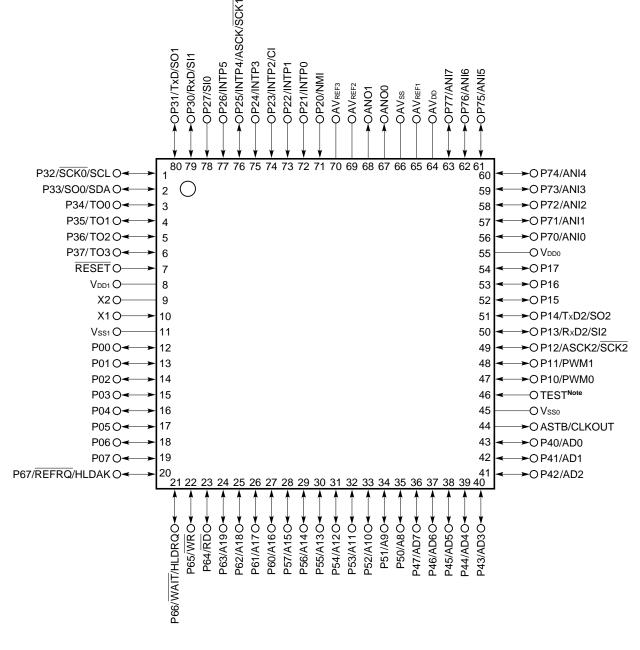
Table 1-1. Differences between the μ PD78P4038 and Masked ROM Products

| Product Name | μPD78P4038 | μPD784035 | μPD784036 | μPD784037 | μPD784038 |
|-------------------------|--|---|------------------------|---------------------------|---------------------------|
| Internal program memory | 128-Kbyte PROM Can be changed to 48 K, 64 K, or 96 Kbytes by IMS | 48-Kbyte masked ROM | 64-Kbyte masked ROM | 96-Kbyte masked ROM | 128-Kbyte masked ROM |
| Internal RAM | 4,352-byte internal RAM Can be changed to 2,048 or 3,584 bytes by IMS | • 2,048-byte internal RAM | | • 3,584-byte internal RAM | • 4,352-byte internal RAM |
| Package | 80-pin plastic QFF | P (14 × 14 × 2.7 mm) P (14 × 14 × 1.4 mm) P (fine pitch) (12 × 12 mm) | | | |

2. PIN CONFIGURATION (TOP VIEW)

(1) Normal operating mode

- **80-pin plastic QFP (14** × **14** × **2.7 mm)**μPD78P4038GC-3B9, μPD78P4038GC-×××-3B9
 - 80-pin plastic QFP (14 \times 14 \times 1.4 mm) μ PD78P4038GC-8BT
 - 80-pin plastic TQFP (fine pitch) (12 \times 12 mm) μ PD78P4038GK-BE9, μ PD78P4038GK- \times
 - 80-pin ceramic WQFN (14 \times 14 mm) μ PD78P4038KK-T



Note Connect the TEST pin to Vsso directly.

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 A8-A19
 : Address bus
 P60-P67
 : Port 6

 AD0-AD7
 : Address/data bus
 P70-P77
 : Port 7

ANI0-ANI7 : Analog input PWM0, PWM1 : Pulse width modulation output

ANO0, ANO1 : Analog output RD : Read strobe

ASCK, ASCK2 : Asynchronous serial clock REFRQ : Refresh request

ASTB : Address strobe RESET : Reset

 AV_DD : Analog power supply : Receive data RxD, RxD2 SCK0-SCK2 AVREF1-AVREF3: Reference voltage : Serial clock AVss : Analog ground SCL : Serial clock CI : Clock input : Serial data SDA **CLKOUT** : Serial input : Clock output SI0-SI2 HLDAK : Hold acknowledge SO0-SO2 : Serial output

HLDRQ : Hold request TEST : Test

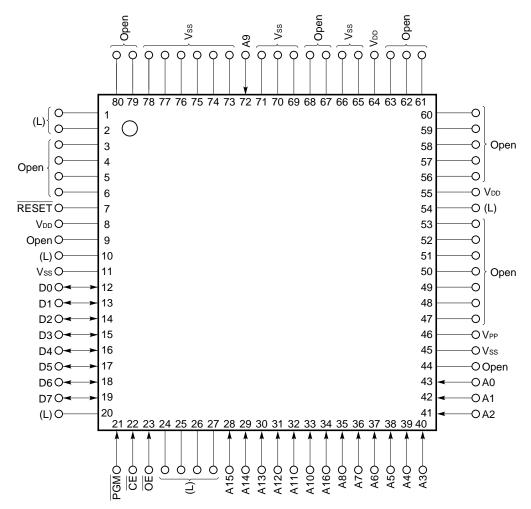
INTP0-INTP5: Interrupt from peripheralsTO0-TO3: Timer outputNMI: Non-maskable interruptTxD, TxD2: Transmit dataP00-P07: Port 0VDD0, VDD1: Power supply

P10-P17 : Port 1 $\frac{\text{Vsso, Vss1}}{\text{WAIT}}$: Ground P20-P27 : Port 2 $\frac{\text{Wait}}{\text{Wait}}$

P50-P57 : Port 5

(2) PROM programming mode

- 80-pin plastic QFP (14 × 14 × 2.7 mm) μ PD78P4038GC-3B9, μ PD78P4038GC-×××-3B9
- 80-pin plastic QFP (14 \times 14 \times 1.4 mm) μ PD78P4038GC-8BT
- 80-pin plastic TQFP (fine pitch) (12 \times 12 mm) μ PD78P4038GK-BE9, μ PD78P4038GK- \times
- 80-pin ceramic WQFN (14 \times 14 mm) μ PD78P4038KK-T



Caution L : Connect these pins separately to the Vss pins through 10-k Ω pull-down resistors.

Vss : To be connected to the ground.

Open: Nothing should be connected on these pins.

RESET: Set a low-level input.

A0-A16 : Address bus RESET : Reset

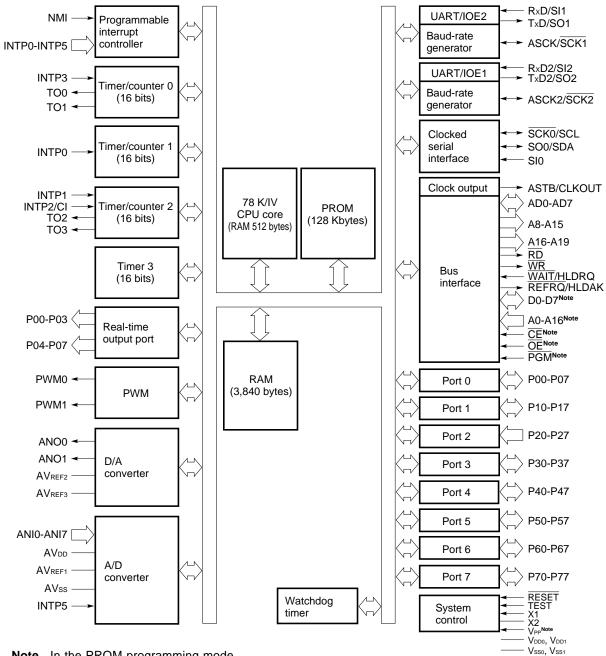
CE : Chip enable VDD : Power supply

D0-D7 : Data bus VPP : Programming power supply

OE : Output enable Vss : Ground

PGM : Program

3. BLOCK DIAGRAM



Note In the PROM programming mode.

4. LIST OF PIN FUNCTIONS

4.1 Pins for Normal Operating Mode

(1) Port pins (1/2)

12

| Pin | I/O | Alternate-Function | Function |
|---------|-------|--------------------|---|
| P00-P07 | I/O | - | Port 0 (P0): • 8-bit I/O port. • Functions as a real-time output port (4 bits × 2). • Inputs and outputs can be specified bit by bit. • The use of the pull-up resistors can be specified by software for the pins in the input mode together. • Can drive a transistor. |
| P10 | I/O | PWM0 | Port 1 (P1): |
| P11 | | PWM1 | 8-bit I/O port. Inpute and outputs can be appointed bit by bit. |
| P12 | | ASCK2/SCK2 | Inputs and outputs can be specified bit by bit. The use of the pull-up resistors can be specified by software for the pins. |
| P13 | | RxD2/SI2 | in the input mode together. |
| P14 | | TxD2/SO2 | Can drive LED. |
| P15-P17 | | _ | |
| P20 | Input | NMI | Port 2 (P2): |
| P21 | | INTP0 | 8-bit input-only port. P20 does not function as a general number port (names) while |
| P22 | | INTP1 | P20 does not function as a general-purpose port (nonmaskable interrupt). However, the input level can be checked by an interrupt |
| P23 | | INTP2/CI | service routine. |
| P24 | | INTP3 | • The use of the pull-up resistors can be specified by software for pins |
| P25 | | INTP4/ASCK/SCK1 | P22 to P27 (in units of 6 bits). • The P25/INTP4/ASCK/SCK1 pin functions as the SCK1 output pin by |
| P26 | | INTP5 | CSIM1. |
| P27 | | SIO | |
| P30 | I/O | RxD/SI1 | Port 3 (P3): |
| P31 | | TxD/SO1 | • 8-bit I/O port. |
| P32 | | SCK0/SCL | Inputs and outputs can be specified bit by bit. The use of the pull-up resistors can be specified by software for the pins. |
| P33 | | SO0/SDA | in the input mode together. |
| P34-P37 | | TO0-TO3 | |
| P40-P47 | I/O | AD0-AD7 | Port 4 (P4): • 8-bit I/O port. • Inputs and outputs can be specified bit by bit. • The use of the pull-up resistors can be specified by software for the pins in the input mode together. • Can drive LED. |

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(1) Port pins (2/2)

| Pin | I/O | Alternate-Function | Function |
|----------------|-----|--------------------|--|
| P50-P57 | I/O | A8-A15 | Port 5 (P5): • 8-bit I/O port. • Inputs and outputs can be specified bit by bit. • The use of the pull-up resistors can be specified by software for the pins in the input mode together. • Can drive LED. |
| P60-P63 P64 | I/O | A16-A19 RD | Port 6 (P6): • 8-bit I/O port. |
| P65 | | WR | Inputs and outputs can be specified bit by bit. The use of the pull-up resistors can be specified by software for the pins |
| P66 | | WAIT/HLDRQ | in the input mode together. |
| P67 | | REFRQ/HLDAK | |
| P70-P77 | I/O | ANIO-ANI7 | Port 7 (P7): • 8-bit I/O port. • Inputs and outputs can be specified bit by bit. |

(2) Non-port pins (1/2)

| Pin | I/O | Alternate-Function | Function | | |
|---------|--------|--------------------|---|--|--|
| TO0-TO3 | Output | P34-P37 | Timer output | | |
| CI | Input | P23/INTP2 | Input of a count clock for timer/counter 2 | | |
| RxD | Input | P30/SI1 | Serial data input (UART0) | | |
| RxD2 | _ ` | P13/SI2 | Serial data input (UART2) | | |
| TxD | Output | P31/SO1 | Serial data output (UART0 | 0) | |
| TxD2 | | P14/SO2 | Serial data output (UART2 | 2) | |
| ASCK | Input | P25/INTP4/SCK1 | Baud rate clock input (UAI | RT0) | |
| ASCK2 | _ ` | P12/SCK2 | Baud rate clock input (UAI | RT2) | |
| SDA | I/O | P33/SO0 | Serial data I/O (2-wire seri | ial I/O) | |
| SI0 | Input | P27 | Serial data input (3-wire se | erial I/O0) | |
| SI1 | | P30/R×D | Serial data input (3-wire se | erial I/O1) | |
| SI2 | | P13/RxD2 | Serial data input (3-wire se | erial I/O2) | |
| SO0 | Output | P33/SDA | Serial data output (3-wire | serial I/O0) | |
| SO1 | | P31/TxD | Serial data output (3-wire | serial I/O1) | |
| SO2 | | P14/TxD2 | Serial data output (3-wire | serial I/O2) | |
| SCK0 | I/O | P32/SCL | Serial clock I/O (3-wire ser | rial I/O0) | |
| SCK1 | | P25/INTP4/ASCK | Serial clock I/O (3-wire ser | rial I/O1) | |
| SCK2 | | P12/ASCK2 | Serial clock I/O (3-wire ser | rial I/O2) | |
| SCL | | P32/SCK0 | Serial clock I/O (2-wire ser | rial I/O) | |
| NMI | Input | P20 | External interrupt request | _ | |
| INTP0 | | P21 | | Input of a count clock for timer/counter 1 Capture/trigger signal for CR11 or CR12 | |
| INTP1 | | P22 | | Input of a count clock for timer/counter 2 Capture/trigger signal for CR22 | |
| INTP2 | | P23/CI | | Input of a count clock for timer/counter 2 Capture/trigger signal for CR21 | |
| INTP3 | | P24 | | Input of a count clock for timer/counter 0 Capture/trigger signal for CR02 | |
| INTP4 | | P25/ASCK/SCK1 | | - | |
| INTP5 | | P26 | | Input of a conversion start trigger for A/D converter | |
| AD0-AD7 | I/O | P40-P47 | Time multiplexing address | /data bus (for connecting external memory) | |
| A8-A15 | Output | P50-P57 | High-order address bus (fo | or connecting external memory) | |
| A16-A19 | Output | P60-P63 | High-order address bus during | address expansion (for connecting external memory) | |
| RD | Output | P64 | Strobe signal output for reading the contents of external memory | | |
| WR | Output | P65 | Strobe signal output for wi | riting on external memory | |
| WAIT | Input | P66/HLDRQ | Wait signal insertion | | |
| REFRQ | Output | P67/HLDAK | Refresh pulse output to ex | ternal pseudo static memory | |
| HLDRQ | Input | P66/WAIT | Input of bus hold request | | |
| HLDAK | Output | P67/REFRQ | Output of bus hold response | | |
| ASTB | Output | CLKOUT | Latch timing output of time multiplexing address (A0-A7) (for connecting external memory) | | |
| CLKOUT | Output | ASTB | Clock output | | |

(2) Non-port pins (2/2)

| Pin | I/O | Alternate-Function | Function |
|-------------------------|--------|--------------------|---|
| RESET | Input | _ | Chip reset |
| X1 | Input | _ | Crystal input for system clock oscillation (A clock pulse can also be input |
| X2 | _ | | to the X1 pin.) |
| ANI0-ANI7 | Input | P70-P77 | Analog voltage inputs for the A/D converter |
| ANO0, ANO1 | Output | _ | Analog voltage inputs for the D/A converter |
| AVREF1 | _ | _ | Application of A/D converter reference voltage |
| AVREF2, AVREF3 | | | Application of D/A converter reference voltage |
| AV _{DD} | | | Positive power supply for the A/D converter |
| AVss | | | Ground for the A/D converter |
| V _{DD0} Note 1 | | | Positive power supply of the port part |
| V _{DD1} Note 1 | | | Positive power supply except for the port part |
| V _{SS0} Note 2 | | | Ground of the port part |
| V _{SS1} Note 2 | | | Ground except for the port part |
| TEST | | | Directly connect to Vsso. (The TEST pin is for the IC test.) |

Notes 1. The potential of the V_{DD0} pin must be equal to that of the V_{DD1} pin.

2. The potential of the Vsso pin must be equal to that of the Vsso pin.

4.2 Pins for PROM Programming Mode (V_{PP} \geq +5 V or +12.5 V, $\overline{\text{RESET}}$ = L)

4.2.1 Pin functions

| Pin Name | I/O | Function | | | |
|-----------------|-------|---|--|--|--|
| V _{PP} | _ | PROM programming mode selection High voltage input during program write or verification | | | |
| RESET | Input | PROM programming mode selection | | | |
| A0-A16 | | Address bus | | | |
| D0-D7 | I/O | Data bus | | | |
| CE | Input | PROM enable input/program pulse input | | | |
| ŌĒ | | Read strobe input to PROM | | | |
| PGM | | Program/program inhibit input during PROM programming mode | | | |
| V _{DD} | - | Positive power supply | | | |
| Vss | - | GND | | | |

4.2.2 Pin functions

(1) VPP (Programming power supply): Input

Input pin for setting the μ PD78P4038 to the PROM programming mode. When the input voltage on this pin is +5 V or more and when $\overline{\text{RESET}}$ input goes low, the μ PD78P4038 enters the PROM programming mode. When $\overline{\text{CE}}$ is made low for V_{PP} = +12.5 V and $\overline{\text{OE}}$ = high, program data on D0 to D7 can be written into the internal PROM cell selected by A0 to A16.

(2) RESET (Reset): Input

Input pin for setting the μ PD78P4038 to the PROM programming mode. When input on this pin is low, and when the input voltage on the V_{PP} pin goes +5 V or more, the μ PD78P4038 enters the PROM programming mode.

(3) A0 to A16 (Address bus): Input

Address bus that selects an internal PROM address (0000H to 1FFFFH)

(4) D0 to D7 (Data bus): I/O

Data bus through which a program is written on or read from internal PROM

(5) CE (Chip enable): Input

This pin inputs the enable signal from internal PROM. When this signal is active, a program can be written or read.

(6) OE (Output enable): Input

This pin inputs the read strobe signal to internal PROM. When this signal is made active for \overline{CE} = low, a one-byte program in the internal PROM cell selected by A0 to A16 can be read onto D0 to D7.

(7) PGM (Program): Input

The input pin for the operation mode control signal of the internal PROM.

Upon activation, writing to the internal PROM is enabled.

Upon inactivation, reading from the internal PROM is enabled.

(8) VDD

Positive power supply pin

(9) Vss

Ground potential pin

4.3 I/O Circuits for Pins and Handling of Unused Pins

Table 4-1 describes the types of I/O circuits for pins and the handling of unused pins.

Figure 4-1 shows the configuration of these various types of I/O circuits.

Table 4-1. Types of I/O Circuits for Pins and Handling of Unused Pins (1/2)

| Pin | I/O Circuit Type | I/O | Recommended Connection Method for Unused Pins |
|----------------------|------------------|--------|--|
| P00-P07 | 5-H | I/O | Input state: To be connected to VDD0 |
| P10/PWM0 P11/PWM1 | | | Output state: To be left open |
| P12/ASCK2/SCK2 | 8-C | | |
| P13/RxD2/SI2 | 5-H | | |
| P14/TxD2/SO2 | 1 | | |
| P15-P17 | | | |
| P20/NMI | 2 | Input | To be connected to VDD0 or Vss0 |
| P21/INTP0 | 1 | | |
| P22/INTP1 | 2-C | | To be connected to VDD0 |
| P23/INTP2/CI | 1 | | |
| P24/INTP3 | | | |
| P25/INTP4/ASCK/SCK1 | 8-C | I/O | Input state: To be connected to VDDO Output state: To be left open |
| P26/INTP5 | 2-C | Input | To be connected to VDD0 |
| P27/SI0 | - | | |
| P30/RxD/SI1 | 5-H | I/O | Input state: To be connected to VDD0 |
| P31/TxD/SO1 | | | Output state: To be left open |
| P32/SCK0/SCL | 10-B | | |
| P33/SO0/SDA | 1 | | |
| P34/T00-P37/T03 | 5-H | | |
| P40/AD0-P47/AD7 | | | |
| P50/A8-P57/A15 | | | |
| P60/A16-P63/A19 | | | |
| P64/RD | | | |
| P65/WR |] | | |
| P66/WAIT/HLDRQ | | | |
| P67/REFRQ/HLDAK |] | | |
| P70/ANI0-P77/ANI7 | 20-A | I/O | Input state: To be connected to VDD0 or VSS0 Output state: To be left open |
| ANO0, ANO1 | 12 | Output | To be left open |
| ASTB/CLKOUT | 4-B | | |

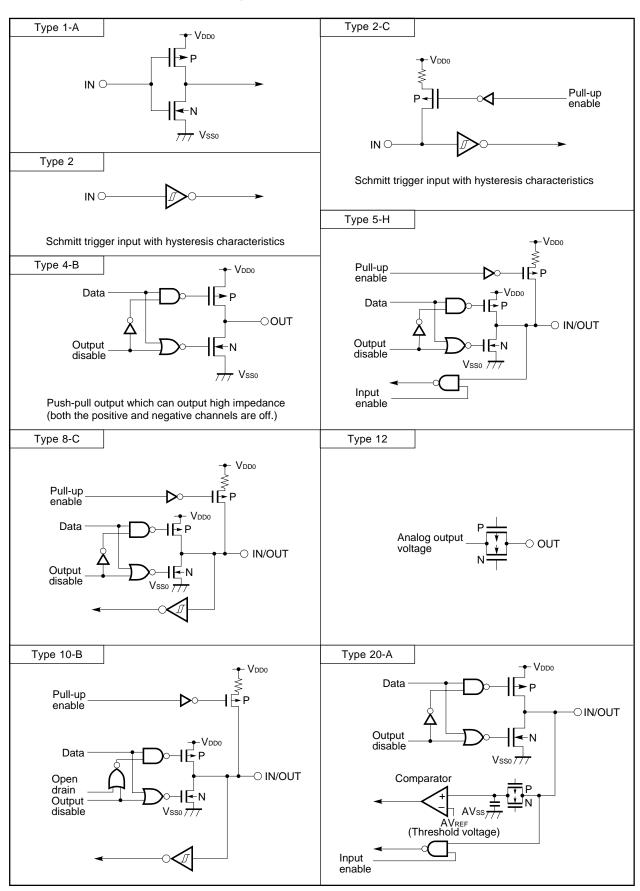
Table 4-1. Types of I/O Circuits for Pins and Handling of Unused Pins (2/2)

| Pin | I/O Circuit Type | I/O | Recommended Connection Method for Unused Pins |
|---------------|------------------|-------|---|
| RESET | 2 | Input | - |
| TEST | 1-A | | To be connected to Vsso directly |
| AVREF1-AVREF3 | _ | | To be connected to Vsso |
| AVss | | | |
| AVDD | | | To be connected to VDD0 |

Caution When the I/O mode of an I/O alternate-function pin is unpredictable, connect the pin to VDDO through a resistor of 10 to 100 kilohms (particularly when the voltage of the reset input pin becomes higher than that of the low level input at power-on or when I/O is switched by software).

Remark Since type numbers are consistent in the 78K Series, those numbers are not always serial in each product. (Some circuits are not included.)

Figure 4-1. I/O Circuits for Pins

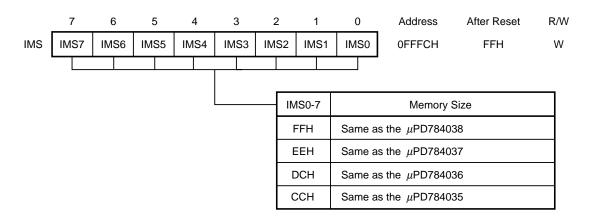


5. INTERNAL MEMORY SWITCHING REGISTER (IMS)

This register enables the software to avoid using part of the internal memory. IMS can be set to establish the same memory mapping as used in ROM products that have different internal memory (ROM and RAM) configurations. IMS is set with 8-bit memory operation instructions.

RESET input sets IMS to FFH.

Figure 5-1. Internal Memory Switching Register (IMS)



IMS is not contained in a mask ROM product (μ PD784035, μ PD784036, μ PD784037, or μ PD784038). But the action is not affected if the write command to IMS is executed to the mask ROM product.

6. PROM PROGRAMMING

The μ PD78P4038 has an on-chip 128-KB PROM device for use as program memory. When programming, set the V_{PP} and $\overline{\text{RESET}}$ pins for PROM programming mode. See **(2)** in **Chapter 2** with regard to handling of other, unused pins.

6.1 Operation Mode

PROM programming mode is selected when +5 V or +12.5 V is added to the $\overline{\text{RESET}}$ pin. This mode can be set to operation mode by setting the $\overline{\text{CE}}$ pin, $\overline{\text{OE}}$ pin, and $\overline{\text{PGM}}$ pin as shown in Table 6-1 below.

In addition, the PROM contents can be read by setting read mode.

Table 6-1. PROM Programming Operation Mode

| Pin | RESET | V _{PP} | V _{DD} | CE | ŌE | PGM | D0-D7 |
|-----------------|-------|-----------------|-----------------|----|----|-----|----------------|
| Operation Mode | | | | | | | |
| Page data latch | L | +12.5 V | +6.5 V | Н | L | Н | Data input |
| Page write | | | | Н | Н | L | High impedance |
| Byte write | | | | L | Н | L | Data input |
| Program verify | | | | L | L | Н | Data output |
| Program inhibit | | | | × | Н | Н | High impedance |
| | | | | × | L | L | |
| Read | | +5 V | +5 V | L | L | Н | Data output |
| Output disable | | | | L | Н | × | High impedance |
| Standby | | | | Н | × | × | High impedance |

Remark $\times = L$ or H

(1) Read mode

Set \overline{CE} to L and \overline{OE} to L to set read mode.

(2) Output disable mode

Set $\overline{\text{OE}}$ to H to set high impedance for data output and output disable mode.

Consequently, if several μ PD78P4038 devices are connected to a data bus, the \overline{OE} pins can be controlled to select data output from any of the devices.

(3) Standby mode

Set $\overline{\mathsf{CE}}$ to H to set standby mode.

In this mode, data output is set to high impedance regardless of the OE setting.

(4) Page data latch mode

At the beginning of page write mode, set \overline{CE} to H, \overline{PGM} to H, and \overline{OE} to L to set page data latch mode. In this mode, 1 page (4 bytes) of data are latched to the internal address/data latch circuit.

(5) Page write mode

After latching the address and data for one page (4 bytes) using page data latch mode, adding a 0.1-ms program pulse (active, low) to the \overline{PGM} pin with both \overline{CE} and \overline{OE} set to H causes page write to be executed. Later, setting both \overline{CE} and \overline{OE} to L causes program verification to be executed.

If programming is not completed after one program pulse, the write and verify operations may be repeated X times (where $X \le 10$).

(6) Byte write mode

Adding a 0.1-ms program pulse (active, low) to the PGM pin with both \overline{CE} and \overline{OE} set to H causes byte write to be executed. Later, setting \overline{OE} to L causes program verification to be executed.

If programming is not completed after one program pulse, the write and verify operations may be repeated X times (where $X \le 10$).

(7) Program verify mode

Set \overline{CE} to L, \overline{PGM} to H, and \overline{OE} to L to set program verify mode. Use verify mode for verification following each write operation.

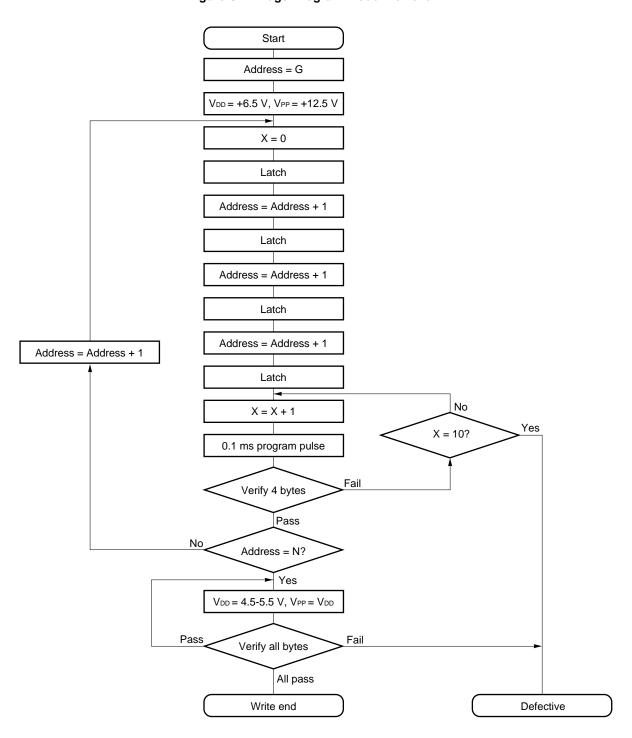
(8) Program inhibit mode

Program inhibit mode is used to write to a single device when several μ PD78P4038 devices are connected in parallel to $\overline{\text{OE}}$, VPP, and D0 to D7 pins.

Use the page write mode or byte write mode described above for each write operation. Write operations cannot be done for devices in which the \overline{PGM} pin has been set to H.

6.2 PROM Write Sequence

Figure 6-1. Page Program Mode Flowchart



Remark G = Start address

N = Program end address

Figure 6-2. Page Program Mode Timing

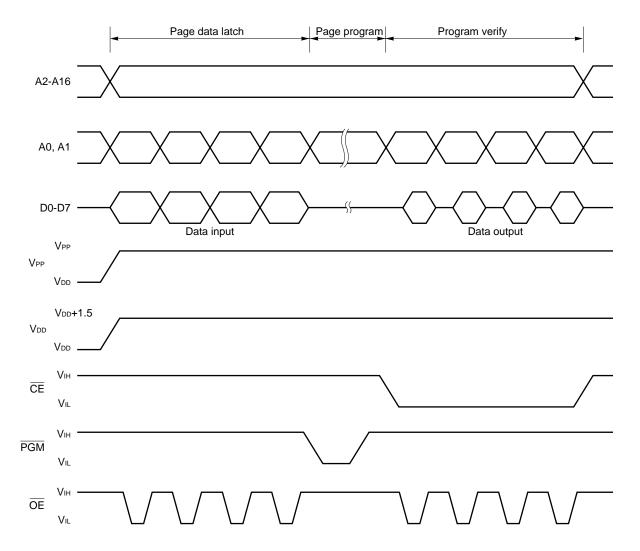
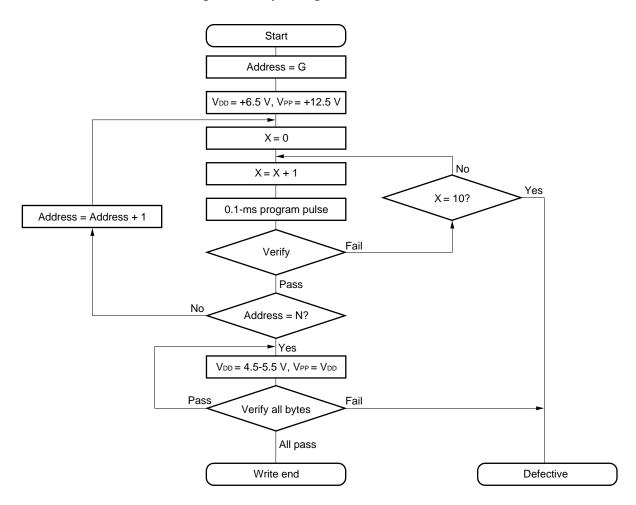


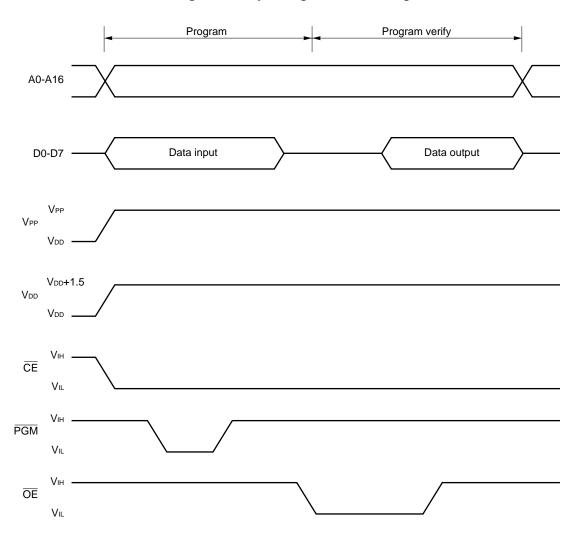
Figure 6-3. Byte Program Mode Flowchart



Remark G = Start address

N = Program end address

Figure 6-4. Byte Program Mode Timing



Cautions 1. Add V_{DD} before V_{PP} , and turn off the V_{DD} after V_{PP} .

- 2. Do not allow VPP to exceed +13.5 V including overshoot.
- 3. Reliability problems may result if the device is inserted or pulled out while +12.5 V is applied at VPP.

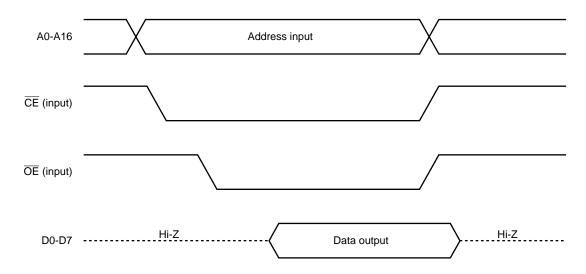
6.3 PROM Read Sequence

Follow this sequence to read the PROM contents to an external data bus (D0 to D7).

- (1) Set the RESET pin to low level and add +5 V to the VPP pin. See (2) in Chapter 2 with regard to handling of other, unused pins.
- (2) Add +5 V to the VDD and VPP pins.
- (3) Input the data address to be read to pins A0 to A16.
- (4) Set read mode.
- (5) Output the data to pins D0 to D7.

Figure 6-5 shows the timing of steps (2) to (5) above.

Figure 6-5. PROM Read Timing



7. ERASURE CHARACTERISTICS (µPD78P4038KK-T ONLY)

Data written in the μ PD78P4038KK-T program memory can be erased (FFH); therefore users can write other data in the memory.

To erase the written data, expose the erasure window to light with a wavelength shorter than approx. 400 nm. Normally, ultraviolet light with a wavelength of 254 nm is employed. The amount of light required to completely erase the data is as follows:

- Intensity of ultraviolet light × erasing time: 57.6 W•s/cm² min.
- Erasing time: About 80 minutes (When using a 12,000 μW/cm² ultraviolet lamp. It may, however, take more time
 due to lamp deterioration, dirt on the erasure window, or the like.)

The ultraviolet lamp should be placed within 2.5 cm from the erasure window during erasure. In addition, if a filter is attached to the ultraviolet lamp, remove the filter before erasure.

8. PROTECTIVE FILM COVERING THE ERASURE WINDOW (μ PD78P4038KK-T ONLY)

To prevent EPROM from being erased inadvertently by light other than that from the lamp used for erasing EPROM, or to prevent the internal circuits other than EPROM from malfunctioning by light, stick a protective film on the erasure window except when EPROM is to be erased.

9. QUALITY

The μ PD78P4038KK-T is not intended for use in mass-produced products; they do not have reliability high enough for such purposes. Their use should be restricted to functional evaluation in experiment or trial manufacture.

10. SCREENING ONE-TIME PROM PRODUCTS

NEC cannot execute a complete test of one-time PROM products (μ PD78P4038GC-3B9, μ PD78P4038GC-8BT, and μ PD78P4038GK-BE9) due to their structure before shipment. It is recommended that you screen (verify) PROM products after writing necessary data into them and storing them at 125°C for 24 hours.

11. ELECTRICAL CHARACTERISTICS

ABSOLUTE MAXIMUM RATINGS $(T_A = 25^{\circ}C)$

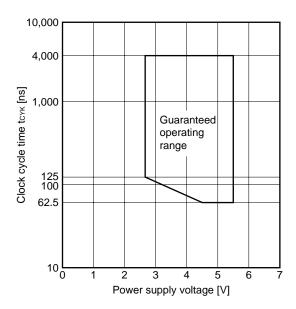
| Parameter | Symbol | Conditions | Rating | Unit |
|---------------------------------------|--------------------|--|-------------------------------|------|
| Supply voltage | V _{DD} | | -0.5 to +7.0 | V |
| | AVDD | | AVss to V _{DD} + 0.5 | V |
| | AVss | | -0.5 to +0.5 | V |
| Input voltage | Vıı | | -0.5 to V _{DD} + 0.5 | V |
| | V ₁₂ | TEST/VPP pin and P21/INTP0/A9 pin in PROM programming mode | -0.5 to +13.5 | V |
| Output voltage | Vo | | -0.5 to V _{DD} + 0.5 | V |
| Output low current | Ю | At one pin | 15 | mA |
| | | Total of all output pins | 100 | mA |
| Output high current | Іон | At one pin | -10 | mA |
| | | Total of all output pins | -100 | mA |
| A/D converter reference input voltage | AV _{REF1} | | -0.5 to V _{DD} + 0.3 | V |
| D/A converter reference input | AV _{REF2} | | -0.5 to V _{DD} + 0.3 | V |
| voltage | AV _{REF3} | | -0.5 to V _{DD} + 0.3 | V |
| Operating ambient temperature | TA | | -40 to +85 | °C |
| Storage temperature | T _{stg} | | -65 to +150 | °C |

Caution Absolute maximum ratings are rated values beyond which physical damage will be caused to the product; if the rated value of any of the parameters in the above table is exceeded, even momentarily, the quality of the product may deteriorate. Always use the product within its rated values.

OPERATING CONDITIONS

Operating ambient temperature (T_A) : -40 to +85°C
 Rise time and fall time (t_r, t_f) (at pins which are not specified) : 0 to 200 μs
 Power supply voltage and clock cycle time : See Figure 11-1.

Figure 11-1. Power Supply Voltage and Clock Cycle Time



CAPACITANCE (TA = 25°C, VDD = Vss = 0 V)

| Parameter | Symbol | Conditions | MIN. | TYP. | MAX. | Unit |
|--------------------|--------|--------------------------------------|------|------|------|------|
| Input capacitance | Cı | f = 1 MHz | | | 10 | pF |
| Output capacitance | Со | 0 V on pins other than measured pins | | | 10 | pF |
| I/O capacitance | Сю | | | | 10 | pF |

OSCILLATOR CHARACTERISTICS ($T_A = -40 \text{ to } +85^{\circ}\text{C}$, $V_{DD} = +4.5 \text{ to } 5.5 \text{ V}$, $V_{SS} = 0 \text{ V}$)

| Resonator | Recommended Circuit | Parameter | MIN. | MAX. | Unit |
|------------------------------|---------------------|---|------|------|------|
| Ceramic resonator or crystal | Vss1 X1 X2 C1 — C2 | Oscillator frequency (fxx) | 4 | 32 | MHz |
| External clock | | X1 input frequency (fx) | 4 | 32 | MHz |
| | X1 X2 | X1 input rise and fall times (txr, txr) | 0 | 10 | ns |
| | HCMOS inverter | X1 input high-level and low-level widths (twxH, twxL) | 10 | 125 | ns |

Caution When using the system clock generator, run wires in the portion surrounded by broken lines according to the following rules to avoid effects such as stray capacitance:

- Minimize the wiring.
- Never cause the wires to cross other signal lines.
- · Never cause the wires to run near a line carrying a large varying current.
- Cause the grounding point of the capacitor of the oscillator circuit to have the same potential as Vss1. Never connect the capacitor to a ground pattern carrying a large current.
- Never extract a signal from the oscillator.

OSCILLATOR CHARACTERISTICS ($T_A = -40 \text{ to } +85^{\circ}\text{C}$, $V_{DD} = +2.7 \text{ to } 5.5 \text{ V}$, $V_{SS} = 0 \text{ V}$)

| Resonator | Recommended Circuit | Parameter | MIN. | MAX. | Unit |
|------------------------------|------------------------|---|------|------|------|
| Ceramic resonator or crystal | V _{SS1} X1 X2 | Oscillator frequency (fxx) | 4 | 16 | MHz |
| External clock | | X1 input frequency (fx) | 4 | 16 | MHz |
| | X1 X2 | X1 input rise and fall times (txr, txr) | 0 | 10 | ns |
| | HCMOS inverter | X1 input high-level and low-level widths (twxH, twxL) | 10 | 125 | ns |

Caution When using the system clock generator, run wires in the portion surrounded by broken lines according to the following rules to avoid effects such as stray capacitance:

- Minimize the wiring.
- · Never cause the wires to cross other signal lines.
- · Never cause the wires to run near a line carrying a large varying current.
- Cause the grounding point of the capacitor of the oscillator circuit to have the same potential as Vss1. Never connect the capacitor to a ground pattern carrying a large current.
- Never extract a signal from the oscillator.

DC CHARACTERISTICS (TA = -40 to +85°C, VDD = AVDD = +2.7 to 5.5 V, Vss = AVss = 0 V) (1/2)

| Parameter | Symbol | Conditions | MIN. | TYP. | MAX. | Unit |
|-----------------------|------------------|--|-----------------------|------|--|------------|
| Input low voltage | V _{IL1} | For pins other than those described in Notes 1, 2, 3, and 4 | -0.3 | | MAX. 0.3Vpd 0.2Vpd +0.8 Vpd + 0.3 Vpd + 0.3 Vpd + 0.3 1.0 | V |
| | V _{IL2} | For pins described in Notes 1, 2, 3, and 4 | -0.3 | | 0.2V _{DD} | V |
| | VIL3 | V_{DD} = +5.0 V ± 10% For pins described in Notes 2, 3, and 4 | -0.3 | | +0.8 | V |
| Input high voltage | V _{IH1} | For pins other than those described in Note 1 | 0.7V _{DD} | | | V |
| | V _{IH2} | For pins described in Note 1 | 0.8Vpb | | V _{DD} + 0.3 | V |
| | VIH3 | V_{DD} = +5.0 V ± 10% For pins described in Notes 2, 3, and 4 | 2.2 | | V _{DD} + 0.3 | |
| Output low voltage | V _{OL1} | IoL = 2 mA | | | 0.4 | V |
| | Vol2 | V_{DD} = +5.0 V ± 10% I_{OL} = 8 mA For pins described in Notes 2 and 5 | | | 1.0 | V |
| Output high voltage | Vон1 | lон = −2 mA | V _{DD} - 1.0 | | | 3 V 3 V |
| | Voн2 | V_{DD} = +5.0 V ± 10% I_{OH} = -5 mA For pins described in Note 4 | V _{DD} - 1.4 | | | V |
| X1 input low current | lι∟ | $\begin{aligned} EXTC &= 0 \\ 0 \ V &\leq V_1 \leq V_{1L2} \end{aligned}$ | | | -30 | μΑ |
| X1 input high current | Іін | $\begin{aligned} &EXTC = 0 \\ &V_{IH2} \leq V_{I} \leq V_{DD} \end{aligned}$ | | | +30 | μΑ |

Notes 1. X1, X2, RESET, P12/ASCK2/SCK2, P20/NMI, P21/INTP0, P22/INTP1, P23/INTP2/CI, P24/INTP3, P25/INTP4/ASCK/SCK1, P26/INTP5, P27/SI0, P32/SCK0/SCL, P33/SO0/SDA, TEST

- **2.** P40/AD0 to P47/AD7, P50/A8 to P57/A15
- **3.** P60/A16 to P63/A19, P64/RD, P65/WR, P66/WAIT/HLDRQ, P67/REFRQ/HLDAK
- **4.** P00 to P07
- **5.** P10 to P17



DC CHARACTERISTICS (TA = -40 to +85°C, VDD = AVDD = +2.7 to 5.5 V, Vss = AVss = 0 V) (2/2)

| Parameter | Symbol | Co | onditions | MIN. | TYP. | MAX. | Unit |
|------------------------|------------------|---|---|------|------|------|------|
| Input leakage current | Iц | $0 \text{ V} \leq V_{I} \leq V_{DD}$ For pins other that | an X1 when EXTC = 0 | | | ±10 | μΑ |
| Output leakage current | ILO | 0 V ≤ Vo ≤ VDD | | | | ±10 | μΑ |
| VDD supply current | I _{DD1} | Operation mode | fxx = 32 MHz V _{DD} = +5.0 V ± 10% | | 25 | 45 | mA |
| | | | fxx = 16 MHz V _{DD} = +2.7 to 3.3 V | | 12 | 25 | mA |
| | I _{DD2} | HALT mode | fxx = 32 MHz V _{DD} = +5.0 V ± 10% | | 13 | 26 | mA |
| | | | fxx = 16 MHz V _{DD} = +2.7 to 3.3 V | | 8 | 12 | mA |
| | IDD3 | IDLE mode (EXTC = 0) | fxx = 32 MHz V _{DD} = +5.0 V ± 10% | | | 12 | mA |
| | | | fxx = 16 MHz V _{DD} = +2.7 to 3.3 V | | | 8 | mA |
| Pull-up resistor | R∟ | V1 = 0 V | | 15 | | 80 | kΩ |

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AC CHARACTERISTICS ($T_A = -40 \text{ to } +85^{\circ}\text{C}$, $V_{DD} = AV_{DD} = +2.7 \text{ to } 5.5 \text{ V}$, $V_{SS} = AV_{SS} = 0 \text{ V}$)

(1) Read/write operation (1/2)

| Parameter | Symbol | С | onditions | MIN. | MAX. | Unit |
|---|---------------|--------------------------------|------------------------------------|------------------|----------------------|------|
| Address setup time | t sast | $V_{DD} = +5.0 \text{ V} \pm$ | 10% | (0.5 + a) T – 15 | | ns |
| | | | | (0.5 + a) T – 31 | | ns |
| ASTB high-level width | twsтн | V _{DD} = +5.0 V ± | 10% | (0.5 + a) T – 17 | | ns |
| | | | | (0.5 + a) T - 40 | | ns |
| Address hold time (to ASTB↓) | thstla | $V_{DD} = +5.0 \text{ V} \pm$ | 10% | 0.5T - 24 | | ns |
| | | | | 0.5T - 34 | | ns |
| Address hold time (to $\overline{RD}\uparrow$) | t HRA | | | 0.5T - 14 | | ns |
| Delay from address to $\overline{\rm RD} {\downarrow}$ | t dar | $V_{DD} = +5.0 \text{ V} \pm$ | : 10% | (1 + a) T – 9 | | ns |
| | | | | (1 + a) T – 15 | | ns |
| Address float time (to $\overline{RD}\downarrow$) | t fra | | | | 0 | ns |
| Delay from address to data input | t DAID | $V_{DD} = +5.0 \text{ V} \pm$ | 10% | | (2.5 + a + n) T - 37 | ns |
| | | | | | (2.5 + a + n) T - 52 | ns |
| Delay from ASTB↓ to data input | tostid | V _{DD} = +5.0 V ± 10% | | | (2 + n) T – 40 | ns |
| | | | | | (2 + n) T - 60 | ns |
| Delay from $\overline{RD} \downarrow$ to data input | torid | V _{DD} = +5.0 V ± | : 10% | | (1.5 + n) T – 50 | ns |
| | | | | | (1.5 + n) T – 70 | ns |
| Delay from ASTB↓ to RD↓ | t DSTR | | | 0.5T – 9 | | ns |
| Data hold time (to \overline{RD}) | thrid | | | 0 | | ns |
| Delay from $\overline{RD} {\uparrow}$ to address active | t dra | After program | $V_{DD} = +5.0 \text{ V} \pm 10\%$ | 0.5T – 8 | | ns |
| | | is read | | 0.5T – 12 | | ns |
| | | After data is | $V_{DD} = +5.0 \text{ V} \pm 10\%$ | 1.5T – 8 | | ns |
| | | read | | 1.5T – 12 | | ns |
| Delay from RD↑ to ASTB↑ | t DRST | | | 0.5T - 17 | | ns |
| RD low-level width | twrL | VDD = +5.0 V ± | 10% | (1.5 + n) T - 30 | | ns |
| | | | | (1.5 + n) T - 40 | | ns |
| Address hold time (to $\overline{WR}\uparrow$) | thwa | | | 0.5T – 14 | | ns |
| Delay from address to $\overline{\text{WR}} \downarrow$ | t DAW | $V_{DD} = +5.0 \text{ V} \pm$ | 10% | (1 + a) T – 5 | | ns |
| | | | | (1 + a) T – 15 | | ns |
| Delay from ASTB↓ to data output | tostod | $V_{DD} = +5.0 \text{ V} \pm$ | 10% | | 0.5T + 19 | ns |
| | | | | | 0.5T + 35 | ns |
| Delay from WR↓ to data output | towod | | | | 0.5T - 11 | ns |
| Delay from ASTB \downarrow to $\overline{WR}\downarrow$ | tostw | | | 0.5T - 9 | | ns |

Remarks T: TCYK (system clock cycle time)

a: 1 (during address wait), otherwise, 0

n: Number of wait states $(n \ge 0)$

(1) Read/write operation (2/2)

| Parameter | Symbol | Conditions | MIN. | MAX. | Unit |
|-----------------------------|--------|--------------------------------|------------------|------|------|
| Data setup time (to WR↑) | tsodw | V _{DD} = +5.0 V ± 10% | (1.5 + n) T – 30 | | ns |
| | | | (1.5 + n) T – 40 | | ns |
| Data hold time (to WR↑)Note | thwod | V _{DD} = +5.0 V ± 10% | 0.5T – 5 | | ns |
| | | | 0.5T - 25 | | ns |
| Delay from WR↑ to ASTB↑ | towst | | 0.5T – 12 | | ns |
| WR low-level width | twwL | V _{DD} = +5.0 V ± 10% | (1.5 + n) T – 30 | | ns |
| | | | (1.5 + n) T – 40 | | ns |

Note The hold time includes the time during which V_{OH1} and V_{OL1} are held under the load conditions of $C_L = 50$ pF and $R_L = 4.7$ k Ω .

Remarks T: TCYK (system clock cycle time)

n: Number of wait states $(n \ge 0)$

(2) Bus hold timing

| Parameter | Symbol | Conditions | MIN. | MAX. | Unit |
|-----------------------------|------------------|--------------------|---------|--------------------|------|
| Delay from HLDRQ↑ to float | t FHQC | | | (6 + a + n) T + 50 | ns |
| Delay from HLDRQ↑ to HLDAK↑ | t dhqhhah | VDD = +5.0 V ± 10% | | (7 + a + n) T + 30 | ns |
| | | | | (7 + a + n) T + 40 | ns |
| Delay from float to HLDAK↑ | t DCFHA | | | 1T + 30 | ns |
| Delay from HLDRQ↓ to HLDAK↓ | t dhqlhal | VDD = +5.0 V ± 10% | | 2T + 40 | ns |
| | | | | 2T + 60 | ns |
| Delay from HLDAK↓ to active | t DHAC | VDD = +5.0 V ± 10% | 1T – 20 | | ns |
| | | | 1T – 30 | | ns |

Remarks T: TCYK (system clock cycle time)

a: 1 (during address wait), otherwise, 0

n: Number of wait states $(n \ge 0)$

(3) External wait timing

| Parameter | Symbol | Conditions | MIN. | MAX. | Unit |
|---|----------------|------------------------------------|-----------------|------------------|------|
| Delay from address to WAIT↓ input | t dawt | V _{DD} = +5.0 V ± 10% | | (2 + a) T – 40 | ns |
| | | | | (2 + a) T - 60 | ns |
| Delay from ASTB↓ to WAIT↓ input | tostwt | V _{DD} = +5.0 V ± 10% | | 1.5T – 40 | ns |
| | | | | 1.5T – 60 | ns |
| Hold time from ASTB↓ to WAIT | thstwth | V _{DD} = +5.0 V ± 10% | (0.5 + n) T + 5 | | ns |
| | | | (0.5 + n) T +10 | | ns |
| Delay from ASTB↓ to WAIT↑ | tostwth | VDD = +5.0 V ± 10% | | (1.5 + n) T – 40 | ns |
| | | | | (1.5 + n) T - 60 | ns |
| Delay from RD↓ to WAIT↓ input | t DRWTL | $V_{DD} = +5.0 \text{ V} \pm 10\%$ | | T – 50 | ns |
| | | | | T – 70 | ns |
| Hold time from $\overline{RD}\downarrow$ to $\overline{WAIT}\downarrow$ | thrwt | $V_{DD} = +5.0 \text{ V} \pm 10\%$ | nT + 5 | | ns |
| | | | nT + 10 | | ns |
| Delay from RD↓ to WAIT↑ | t DRWTH | $V_{DD} = +5.0 \text{ V} \pm 10\%$ | | (1 + n) T - 40 | ns |
| | | | | (1 + n) T - 60 | ns |
| Delay from WAIT↑ to data input | towtid | $V_{DD} = +5.0 \text{ V} \pm 10\%$ | | 0.5T – 5 | ns |
| | | | | 0.5T – 10 | ns |
| Delay from WAIT↑ to WR↑ | towtw | | 0.5T | | ns |
| Delay from WAIT↑ to RD↑ | towtr | | 0.5T | | ns |
| Delay from WR↓ to WAIT↓ input | towwtl | $V_{DD} = +5.0 \text{ V} \pm 10\%$ | | T – 50 | ns |
| | | | | T – 75 | ns |
| Hold time from WR↓ to WAIT | tнwwт | $V_{DD} = +5.0 \text{ V} \pm 10\%$ | nT + 5 | | ns |
| | | | nT + 10 | | ns |
| Delay from WR↓ to WAIT↑ | towwth | V _{DD} = +5.0 V ± 10% | | (1 + n) T – 40 | ns |
| | | | | (1 + n) T – 70 | ns |

Remarks T: TCYK (system clock cycle time)

a: 1 (during address wait), otherwise, 0

n: Number of wait states (n \geq 0)

(4) Refresh timing

| Parameter | Symbol | Conditions | MIN. | MAX. | Unit |
|------------------------------|-----------------|--------------------------------|-----------|------|------|
| Random read/write cycle time | t RC | | ЗТ | | ns |
| REFRQ low-level pulse width | twrfql | VDD = +5.0 V ± 10% | 1.5T – 25 | | ns |
| | | | 1.5T – 30 | | ns |
| Delay from ASTB↓ to REFRQ | t DSTRFQ | | 0.5T – 9 | | ns |
| Delay from RD↑ to REFRQ | t DRRFQ | | 1.5T – 9 | | ns |
| Delay from WR↑ to REFRQ | t DWRFQ | | 1.5T – 9 | | ns |
| Delay from REFRQ↑ to ASTB | t DRFQST | | 0.5T – 15 | | ns |
| REFRQ high-level pulse width | twrfqh | V _{DD} = +5.0 V ± 10% | 1.5T – 25 | | ns |
| | | | 1.5T – 30 | | ns |

Remark T: TCYK (system clock cycle time)

SERIAL OPERATION (TA = -40 to +85°C, VDD = +2.7 to 5.5 V, AVss = Vss = 0 V)

(1) CSI

| Parameter | Symbol | | Conditions | MIN. | MAX. | Unit |
|--------------------------------------|---------|-------|--|--------------|-------------|------|
| Serial clock cycle time (SCK0) | tcysko | Input | External clock When SCK0 and SO0 are CMOS I/O | 10/fxx + 380 | | ns |
| | | Outpu | t | Т | | μs |
| Serial clock low-level width (SCK0) | twskLo | Input | External clock When SCK0 and SO0 are CMOS I/O | 5/fxx + 150 | | ns |
| | | Outpu | t | 0.5T - 40 | | μs |
| Serial clock high-level width (SCK0) | twskH0 | Input | External clock When SCK0 and SO0 are CMOS I/O | 5/fxx + 150 | | ns |
| | | Outpu | t | 0.5T - 40 | | μs |
| SI0 setup time (to SCK0↑) | tsssko | | | 40 | | ns |
| SI0 hold time (to SCK0↑) | thssk0 | | | 5/fxx + 40 | | ns |
| SO0 output delay time (to SCK0↓) | tosbsk1 | | S push-pull output e serial I/O mode) | 0 | 5/fxx + 150 | ns |
| | tosbsk2 | | drain output e serial I/O mode), $R_L = 1 \text{ k}\Omega$ | 0 | 5/fxx + 400 | ns |

Remarks 1. The values in this table are those when C_L is 100 pF.

2. T : Serial clock cycle set by software. The minimum value is 16/fxx.

3. fxx: Oscillator frequency

(2) IOE1, IOE2

| Parameter | Symbol | | Conditions | MIN. | MAX. | Unit |
|--|--------|---------|--------------------------------|----------------|------|------|
| Serial clock cycle time | tcysk1 | Input | V _{DD} = +5.0 V ± 10% | 250 | | ns |
| (SCK1, SCK2) | | | | 500 | | ns |
| | | Output | Internal, divided by 16 | Т | | ns |
| Serial clock low-level width | twskL1 | Input | V _{DD} = +5.0 V ± 10% | 85 | | ns |
| (SCK1, SCK2) | | | | 210 | | ns |
| | | Output | Internal, divided by 16 | 0.5T - 40 | | ns |
| Serial clock high-level width | twskH1 | Input | V _{DD} = +5.0 V ± 10% | 85 | | ns |
| (SCK1, SCK2) | | | | 210 | | ns |
| | | Output | Internal, divided by 16 | 0.5T - 40 | | ns |
| Setup time for SI1 and SI2 (to SCK1, SCK2↑) | tsssk1 | | | 40 | | ns |
| Hold time for SI1 and SI2 (to SCK1, SCK2↑) | thssk1 | | | 40 | | ns |
| Output delay time for SO1 and SO2 (to SCK1, SCK2↓) | tososk | | | 0 | 50 | ns |
| Output hold time for SO1 and SO2 (to SCK1, SCK2↑) | thsosk | When da | ata is transferred | 0.5tсүзк1 — 40 | | ns |

Remarks 1. The values in this table are those when C_L is 100 pF.

2. T: Serial clock cycle set by software. The minimum value is 16/fxx.

(3) UART, UART2

| Parameter | Symbol | Conditions | MIN. | MAX. | Unit |
|-----------------------------|--------|--------------------------------|------|------|------|
| ASCK clock input cycle time | tcyask | V _{DD} = +5.0 V ± 10% | 125 | | ns |
| | | | 250 | | ns |
| ASCK clock low-level width | twaskl | V _{DD} = +5.0 V ± 10% | 52.5 | | ns |
| | | | 85 | | ns |
| ASCK clock high-level width | twaskh | V _{DD} = +5.0 V ± 10% | 52.5 | | ns |
| | | | 85 | | ns |

CLOCK OUTPUT OPERATION

| Parameter | Symbol | Conditions | MIN. | MAX. | Unit |
|-------------------------|--------|--------------------------------|---------------|------|------|
| CLKOUT cycle time | tcycL | | nT | | ns |
| CLKOUT low-level width | tcll | V _{DD} = +5.0 V ± 10% | 0.5tcycL - 10 | | ns |
| | | | 0.5tcycL - 20 | | ns |
| CLKOUT high-level width | tсьн | V _{DD} = +5.0 V ± 10% | 0.5tcycL - 10 | | ns |
| | | | 0.5tcycL - 20 | | ns |
| CLKOUT rise time | tclr | V _{DD} = +5.0 V ± 10% | | 10 | ns |
| | | | | 20 | ns |
| CLKOUT fall time | tclf | V _{DD} = +5.0 V ± 10% | | 10 | ns |
| | | | | 20 | ns |

Remarks n: Divided frequency ratio set by software in the CPU (n = 1, 2, 4, 8, 16)

T: TCYK (system clock cycle time)

OTHER OPERATIONS

| | Parameter | Symbol | Conditions | MIN. | MAX. | Unit |
|---|---|----------------|------------|---------|------|------|
| | NMI low-level width | twnil | | 10 | | μs |
| | NMI high-level width | twnih | | 10 | | μs |
| * | INTP0 low-level width | t witol | | 4tсүзмр | | ns |
| * | INTP0 high-level width | twiтон | | 4tсүзмр | | ns |
| * | Low-level width for INTP1-INTP3 and CI | twiT1L | | 4tсүсри | | ns |
| * | High-level width for INTP1-INTP3 and CI | twiT1H | | 4tсүсри | | ns |
| | Low-level width for INTP4 and INTP5 | twiT2L | | 10 | | μs |
| | High-level width for INTP4 and INTP5 | twit2H | | 10 | | μs |
| | RESET low-level width | twrsl | | 10 | | μs |
| | RESET high-level width | twrsh | | 10 | | μs |

Remarks tcysmp: Sampling clock set by software

tcycpu: CPU operation clock set by software in the CPU

A/D CONVERTER CHARACTERISTICS

 $(T_A = -40 \text{ to } +85^{\circ}\text{C}, V_{DD} = AV_{DD} = AV_{REF1} = +2.7 \text{ to } 5.5 \text{ V}, V_{SS} = AV_{SS} = 0 \text{ V})$

| Parameter | Symbol | Conditions | MIN. | TYP. | MAX. | Unit |
|---------------------------------|-------------------|--|------|-------|--------------|--------------|
| Resolution | | | 8 | | | bit |
| Total errorNote | | $V_{DD} = AV_{DD} = +5.0 \text{ V} \pm 10\%$ | | | 1.0 | % |
| | | $V_{DD} = AV_{DD} = +2.7 \text{ to } 4.5 \text{ V}$ $T_A = -10 \text{ to } +85^{\circ}\text{C}$ | | | 1.0 | % |
| Linearity calibrationNote | | | | | 0.8 | % |
| Quantization error | | | | | ±1/2 | LSB |
| Conversion time | tconv | FR = 1 | 120 | | | t cyk |
| | | FR = 0 | 180 | | | t cyk |
| Sampling time | t SAMP | FR = 1 | 24 | | | t cyk |
| | | FR = 0 | 36 | | | t cyk |
| Analog input voltage | VIAN | | -0.3 | | AVREF1 + 0.3 | V |
| Analog input impedance | Ran | | | 1,000 | | $M\Omega$ |
| AVREF1 current | AIREF1 | | | 0.5 | 1.5 | mA |
| AV _{DD} supply current | Al _{DD1} | fxx = 32 MHz, CS = 1 | | 2.0 | 5.0 | mA |
| | AI _{DD2} | STOP mode, CS = 0 | | 1.0 | 20 | μΑ |

Note Quantization error is not included. This parameter is indicated as the ratio to the full-scale value.

Remark toyk: System clock cycle time



D/A CONVERTER CHARACTERISTICS (TA = -40 to +85°C, VDD = AVDD = +2.7 to 5.5 V, Vss = AVss = 0 V)

| Parameter | Symbol | Co | onditions | MIN. | TYP. | MAX. | Unit |
|---|--------------------|---------------------------------------|--|---------------------|------|---------------------|------|
| Resolution | | | | 8 | | | bit |
| Total error | | Load conditions: 4 M Ω , 30 pF | VDD = AVDD = AVREF2 = +2.7 to 5.5 V AVREF3 = 0 V | | | 0.6 | % |
| | | | VDD = AVDD = +2.7 to 5.5 V AVREF2 = 0.75VDD AVREF3 = 0.25VDD | | | 0.8 | % |
| | | Load conditions: 2 MΩ, 30 pF | VDD = AVDD = AVREF2 = +2.7 to 5.5 V AVREF3 = 0 V | | | 0.8 | % |
| | | | V _{DD} = AV _{DD} = +2.7 to 5.5 V AV _{REF2} = 0.75V _{DD} AV _{REF3} = 0.25V _{DD} | | | 1.0 | % |
| Settling time | | Load conditions: | 2 MΩ, 30 pF | | | 10 | μs |
| Output resistance | Ro | DACS0, 1 = 55 H | I | | 10 | | kΩ |
| Analog reference voltage | AV _{REF2} | | | 0.75V _{DD} | | V _{DD} | V |
| | AV _{REF3} | | | 0 | | 0.25V _{DD} | V |
| Resistance of AV _{REF2} and A _{VREF3} | RAIREF | DACS0, 1 = 55 H | I | 4 | 8 | | kΩ |
| Reference power supply | Alref2 | | | 0 | | 5 | mA |
| input current | Alref3 | | | -5 | | 0 | mA |

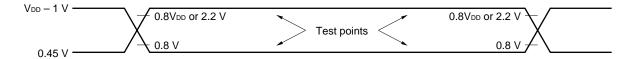
www.DataSheet4U.com

DATA RETENTION CHARACTERISTICS ($T_A = -40 \text{ to } +85^{\circ}\text{C}$)

| Parameter | Symbol | Conditions | MIN. | TYP. | MAX. | Unit |
|---|--------------|-----------------------------------|----------|------|----------|------|
| Data retention voltage | VDDDR | STOP mode | 2.5 | | 5.5 | V |
| Data retention current | Idddr | V _{DDDR} = +2.7 to 5.5 V | | 30 | 50 | μΑ |
| | | V _{DDDR} = +2.5 V | | 10 | 40 | μΑ |
| V _{DD} rise time | t RVD | | 200 | | | μs |
| V _{DD} fall time | t FVD | | 200 | | | μs |
| V _{DD} hold time (to STOP mode setting) | thvd | | 0 | | | ms |
| STOP clear signal input time | torel | | 0 | | | ms |
| Oscillation settling time | twait | Crystal | 30 | | | ms |
| | | Ceramic resonator | 5 | | | ms |
| Input low voltage | VIL | Specific pinsNote | 0 | | 0.1VDDDR | V |
| Input high voltage | ViH | | 0.9Vdddr | | VDDDR | V |

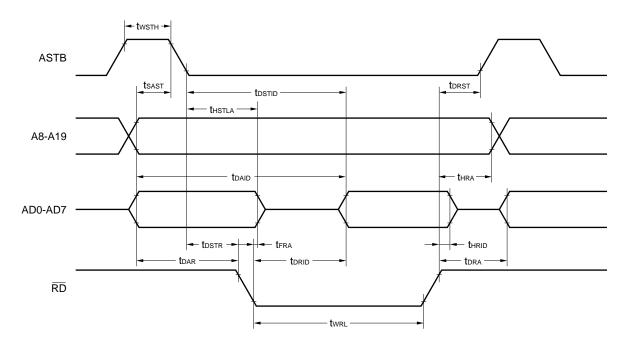
Note RESET, P20/NMI, P21/INTP0, P22/INTP1, P23/INTP2/CI, P24/INTP3, P25/INTP4/ASCK/SCK1, P26/INTP5, P27/SI0, P32/SCK0/SCL, and P33/SO0/SDA pins

AC TIMING TEST POINTS

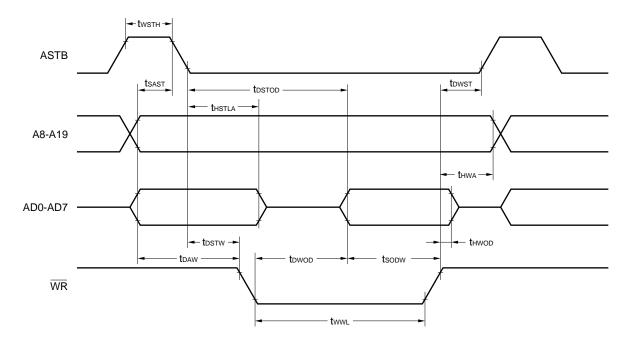


TIMING WAVEFORM

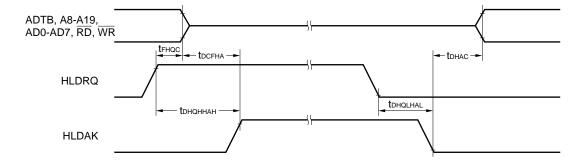
(1) Read operation



(2) Write operation

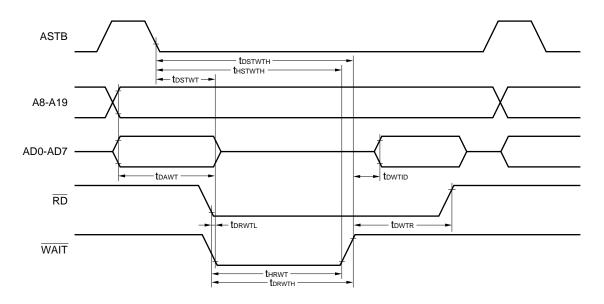


HOLD TIMING

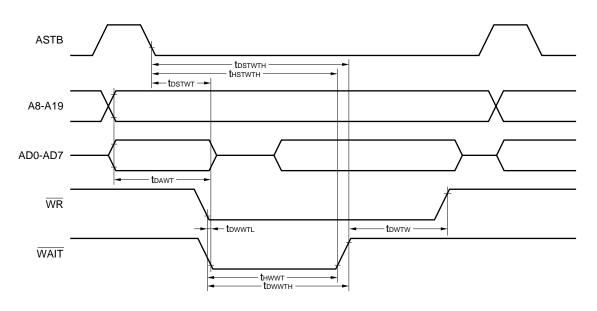


EXTERNAL WAIT SIGNAL INPUT TIMING

(1) Read operation

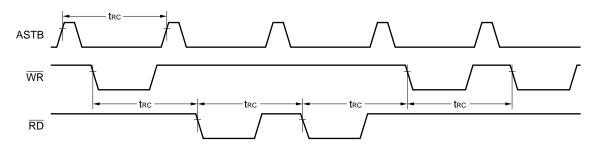


(2) Write operation

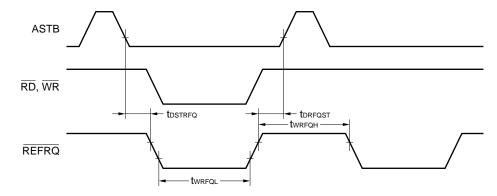


REFRESH TIMING WAVEFORM

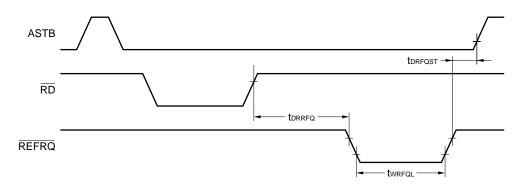
(1) Random read/write cycle



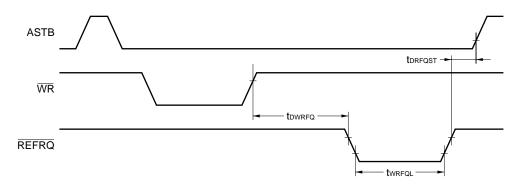
(2) When refresh memory is accessed for a read and write at the same time



(3) Refresh after a read

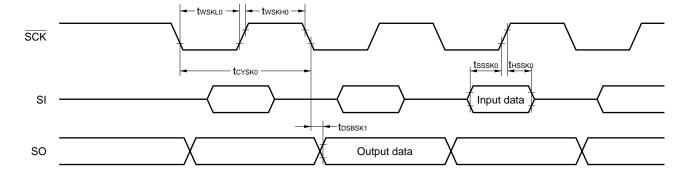


(4) Refresh after a write

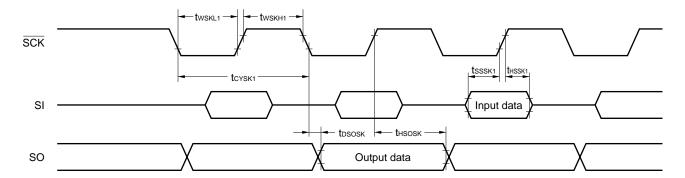


SERIAL OPERATION

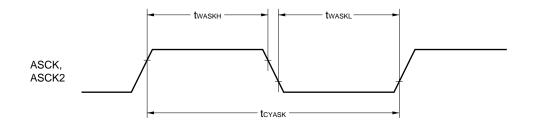
(1) CSI



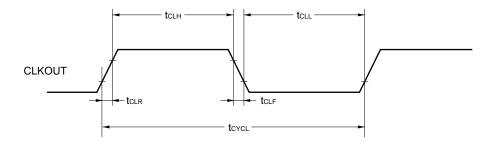
(2) IOE1, IOE2



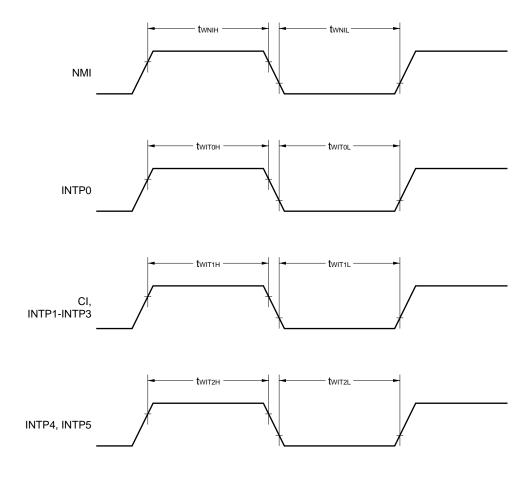
(3) UART, UART2



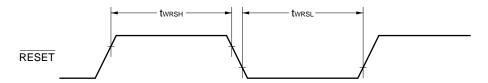
CLOCK OUTPUT TIMING



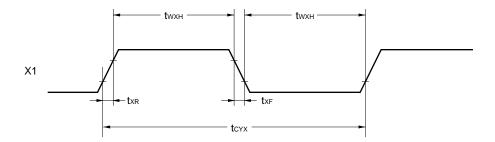
INTERRUPT INPUT TIMING



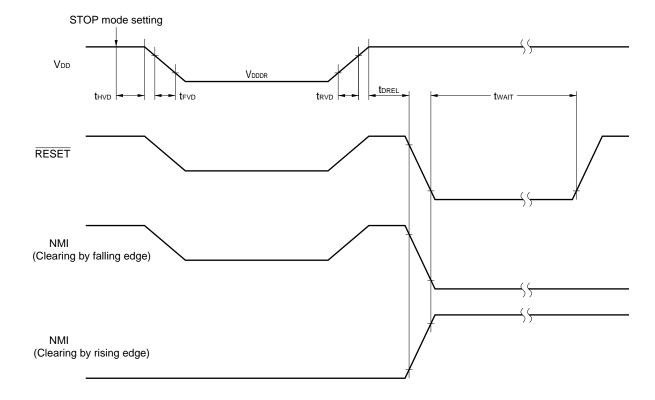
RESET INPUT TIMING



EXTERNAL CLOCK TIMING



DATA RETENTION CHARACTERISTICS





DC PROGRAMMING CHARACTERISTICS (TA = 25 ± 5 °C, Vss = 0 V)

| Parameter | Symbol | SymbolNote 1 | Conditions | MIN. | TYP. | MAX. | Unit |
|---------------------------------|--------|-----------------|--------------------------------|------|------------|------------|------|
| High-level input voltage | Vıн | Vін | | 2.2 | | VDDP + 0.3 | V |
| Low-level input voltage | VIL | VıL | | -0.3 | | +0.8 | V |
| Input leakage current | ILIP | lu | $0 \le V_I \le V_{DDP}$ Note 2 | | | ±10 | μΑ |
| High-level output voltage | Vон | Vон | Іон = -400 μA | 2.4 | | | V |
| Low-level output voltage | Vol | Vol | IoL = 2.1 mA | | | 0.45 | V |
| Output leakage current | Іго | - | 0 ≤ Vo ≤ VDDP, OE = VIH | | | ±10 | μΑ |
| V _{DDP} supply voltage | VDDP | Vcc | Program memory write mode | 6.25 | 6.5 | 6.75 | V |
| | | | Program memory read mode | 4.5 | 5.0 | 5.5 | V |
| V _{PP} supply voltage | VPP | V _{PP} | Program memory write mode | 12.2 | 12.5 | 12.8 | V |
| | | | Program memory read mode | | VPP = VDDP | | V |
| VDDP supply current | loo | loo | Program memory write mode | | 10 | 40 | mA |
| | | | Program memory read mode | | 10 | 40 | mA |
| VPP supply current | IPP | I PP | Program memory write mode | | 5 | 50 | mA |
| | | | Program memory read mode | | 1.0 | 100 | μΑ |

Notes 1. Symbols for the corresponding $\mu PD27C1001A$

2. The V_{DDP} represents the V_{DD} pin as viewed in the programming mode.

AC PROGRAMMING CHARACTERISTICS (TA = 25 ± 5 °C, Vss = 0 V)

PROM Write Mode (Page Program Mode)

| Parameter | Symbol ^{Note 1} | Conditions | MIN. | TYP. | MAX. | Unit |
|----------------------------------|--------------------------|------------|-------|------|-------|------|
| Address setup time | tas | | 2 | | | μs |
| CE set time | tces | | 2 | | | μs |
| Input data setup time | tos | | 2 | | | μs |
| Address hold time | tан | | 2 | | | μs |
| | tahl | | 2 | | | μs |
| | tahv | | 0 | | | μs |
| Input data hold time | tон | | 2 | | | μs |
| Output data hold time | tor | | 0 | | 130 | ns |
| V _{PP} setup time | tvps | | 2 | | | μs |
| VDDP setup time | t _{VDS} Note 2 | | 2 | | | μs |
| Initial program pulse width | tpw | | 0.095 | 0.1 | 0.105 | ms |
| OE set time | toes | | 2 | | | μs |
| Valid data delay time from OE | toe | | | 1 | 2 | ns |
| OE pulse width in the data latch | tıw | | 1 | | | μs |
| PGM setup time | t pgms | | 2 | | | μs |
| CE hold time | tсен | | 2 | | | μs |
| OE hold time | tоен | | 2 | | | μs |

Notes 1. These symbols (except tvps) correspond to those of the corresponding μ PD27C1001A.

2. For μ PD27C1001A, read tvps as tvcs.

PROM Write Mode (Byte Program Mode)

| Parameter | Symbol ^{Note 1} | Conditions | MIN. | TYP. | MAX. | Unit |
|-------------------------------|--------------------------|------------|-------|------|-------|------|
| Address setup time | tas | | 2 | | | μs |
| CE set time | tces | | 2 | | | μs |
| Input data setup time | t os | | 2 | | | μs |
| Address hold time | tан | | 2 | | | μs |
| Input data hold time | tон | | 2 | | | μs |
| Output data hold time | t DF | | 0 | | 130 | ns |
| V _{PP} setup time | tvps | | 2 | | | μs |
| VDDP setup time | t _{VDS} Note 2 | | 2 | | | μs |
| Initial program pulse width | tpw | | 0.095 | 0.1 | 0.105 | ms |
| OE set time | toes | | 2 | | | μs |
| Valid data delay time from OE | toE | | | 1 | 2 | ns |

Notes 1. These symbols (except typs) correspond to those of the corresponding μ PD27C1001A.

2. For μ PD27C1001A, read tvps as tvcs.

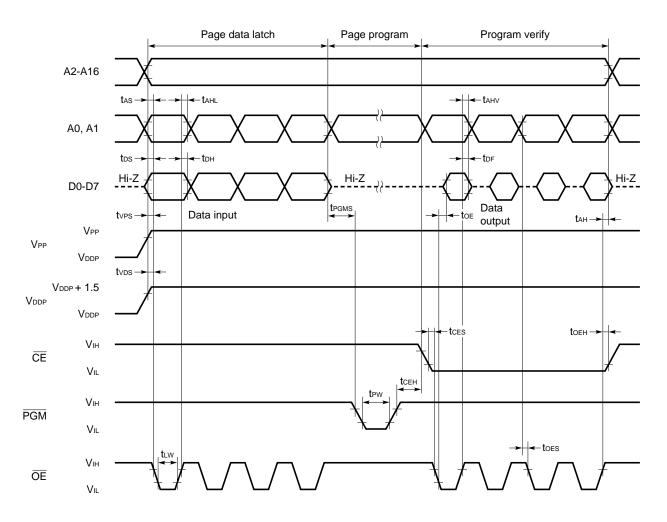
PROM Read Mode

| Parameter | SymbolNote 1 | Conditions | MIN. | TYP. | MAX. | Unit |
|---|--------------|----------------------|------|------|------|------|
| Data output time from address | tacc | CE = OE = VIL | | | 200 | ns |
| Delay from CE ↓ to data output | tce | OE = VIL | | 1 | 2 | μs |
| Delay from $\overline{\sf OE}\ \downarrow$ to data output | toe | CE = VIL | | 1 | 2 | μs |
| Data hold time to OE↑ or CE↑Note 2 | tor | CE = VIL or OE = VIL | 0 | | 60 | ns |
| Data hold time to address | tон | CE = OE = VIL | 0 | | | ns |

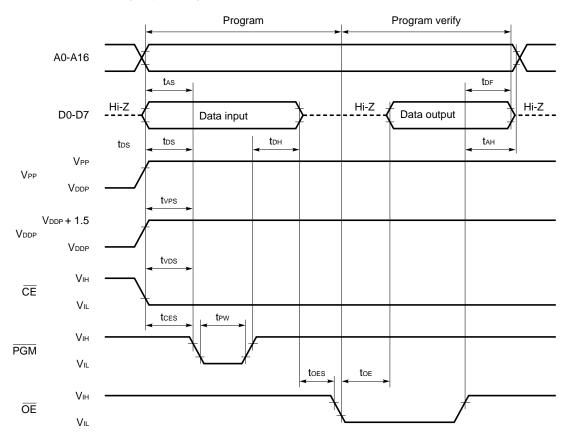
Notes 1. These symbols correspond to those of the corresponding μ PD27C1001A.

2. tdF is the time measured from when either \overline{OE} or \overline{CE} reaches ViH, whichever is faster.

PROM Write Mode Timing (Page Program Mode)

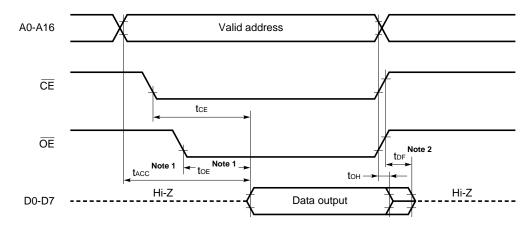


PROM Write Mode Timing (Byte Program Mode)



- Cautions 1. VDDP must be applied before VPP, and must be cut after VPP.
 - 2. VPP including overshoot must not exceed +13.5 V.
 - 3. Plugging in or out the board with the VPP pin supplied with +12.5 V may adversely affect its reliability.

PROM Read Mode Timing

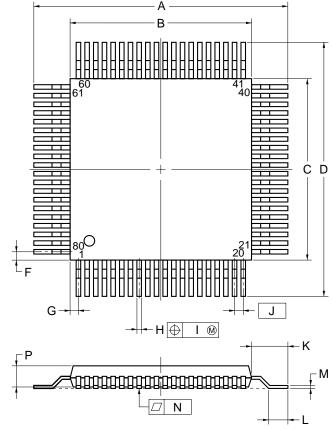


Notes 1. For reading within tacc, the delay of the \overline{OE} input from falling edge of \overline{CE} must be within tacc-toe.

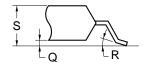
2. tDF is the time measured from when either \overline{OE} or \overline{CE} reaches VIH, whichever is faster.

12. PACKAGE DRAWINGS

80 PIN PLASTIC QFP (14x14)



detail of lead end



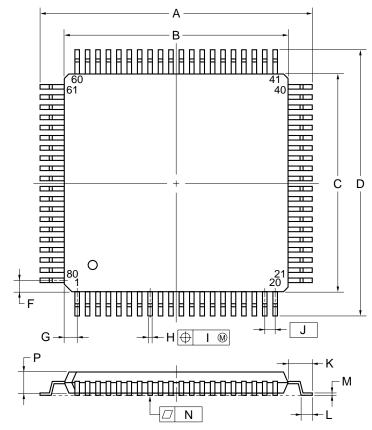
NOTE

Each lead centerline is located within 0.13 mm (0.005 inch) of its true position (T.P.) at maximum material condition.

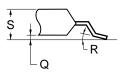
| ITEM | MILLIMETERS | INCHES |
|------|--------------------------------|---|
| Α | 17.2±0.4 | 0.677±0.016 |
| В | 14.0±0.2 | $0.551^{+0.009}_{-0.008}$ |
| С | 14.0±0.2 | $0.551^{+0.009}_{-0.008}$ |
| D | 17.2±0.4 | 0.677±0.016 |
| F | 0.825 | 0.032 |
| G | 0.825 | 0.032 |
| Н | 0.30±0.10 | 0.012+0.004 |
| I | 0.13 | 0.005 |
| J | 0.65 (T.P.) | 0.026 (T.P.) |
| K | 1.6±0.2 | 0.063 ± 0.008 |
| L | 0.8±0.2 | 0.031+0.009 |
| М | 0.15 ^{+0.10} -0.05 | $0.006^{+0.004}_{-0.003}$ |
| N | 0.10 | 0.004 |
| Р | 2.7±0.1 | 0.106 ^{+0.005} _{-0.004} |
| Q | 0.1±0.1 | 0.004±0.004 |
| R | 5°±5° | 5°±5° |
| S | 3.0 MAX. | 0.119 MAX. |

S80GC-65-3B9-5

80 PIN PLASTIC QFP (14×14)



detail of lead end



NOTE

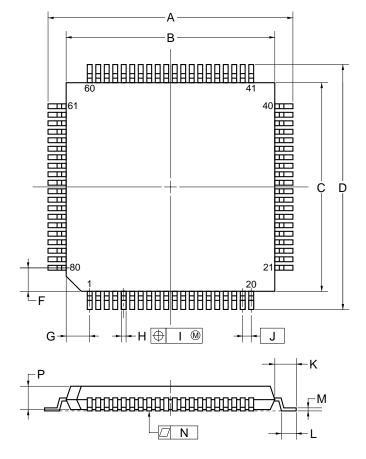
Each lead centerline is located within 0.13 mm (0.005 inch) of its true position (T.P.) at maximum material condition.

| ITEM | MILLIMETERS | INCHES |
|------|------------------|---------------------------|
| Α | 17.20±0.20 | 0.677±0.008 |
| В | 14.00±0.20 | $0.551^{+0.009}_{-0.008}$ |
| С | 14.00±0.20 | $0.551^{+0.009}_{-0.008}$ |
| D | 17.20±0.20 | 0.677±0.008 |
| F | 0.825 | 0.032 |
| G | 0.825 | 0.032 |
| Н | 0.32±0.06 | $0.013^{+0.002}_{-0.003}$ |
| 1 | 0.13 | 0.005 |
| J | 0.65 (T.P.) | 0.026 (T.P.) |
| K | 1.60±0.20 | 0.063±0.008 |
| L | 0.80±0.20 | $0.031^{+0.009}_{-0.008}$ |
| М | 0.17 +0.03 -0.07 | 0.007+0.001 |
| N | 0.10 | 0.004 |
| Р | 1.40±0.10 | 0.055±0.004 |
| Q | 0.125±0.075 | 0.005±0.003 |
| R | 3°+7° | 3°+7° -3° |
| S | 1.70 MAX. | 0.067 MAX. |

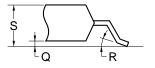
P80GC-65-8BT

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80 PIN PLASTIC TQFP (FINE PITCH) (12×12)



detail of lead end



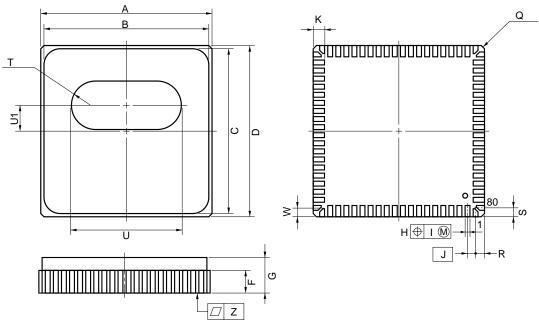
NOTE

Each lead centerline is located within 0.10 mm (0.004 inch) of its true position (T.P.) at maximum material condition.

| ITEM | MILLIMETERS | INCHES |
|------|-----------------------------------|---------------------------|
| Α | 14.00±0.20 | 0.551±0.008 |
| В | 12.00±0.20 | $0.472^{+0.009}_{-0.008}$ |
| С | 12.00±0.20 | $0.472^{+0.009}_{-0.008}$ |
| D | 14.00±0.20 | 0.551±0.008 |
| F | 1.25 | 0.049 |
| G | 1.25 | 0.049 |
| Н | $0.22^{+0.05}_{-0.04}$ | 0.009±0.002 |
| I | 0.10 | 0.004 |
| J | 0.50 (T.P.) | 0.020 (T.P.) |
| K | 1.00±0.20 | $0.039^{+0.009}_{-0.008}$ |
| L | 0.50±0.20 | 0.020+0.008 |
| М | 0.145 ^{+0.055} -0.045 | 0.006±0.002 |
| N | 0.10 | 0.004 |
| Р | 1.05 | 0.041 |
| Q | 0.10±0.05 | 0.004±0.002 |
| R | 5°±5° | 5°±5° |
| S | 1.27 MAX. | 0.050 MAX. |

P80GK-50-BE9-5

80 PIN CERAMIC WQFN



NOTE

Each lead centerline is located within 0.06 mm (0.003 inch) of its true position (T.P.) at maximum material condition.

X80KW-65A-1

| ITEM | MILLIMETERS | INCHES |
|------|-------------|---------------------------|
| Α | 14.0±0.2 | 0.551±0.008 |
| В | 13.6 | 0.535 |
| С | 13.6 | 0.535 |
| D | 14.0±0.2 | 0.551±0.008 |
| F | 1.84 | 0.072 |
| G | 3.6 MAX. | 0.142 MAX. |
| Н | 0.45±0.10 | $0.018^{+0.004}_{-0.005}$ |
| I | 0.06 | 0.003 |
| J | 0.65 (T.P.) | 0.024 (T.P.) |
| K | 1.0±0.15 | 0.039+0.007 |
| Q | C 0.3 | C 0.012 |
| R | 0.825 | 0.032 |
| S | 0.825 | 0.032 |
| Т | R 2.0 | R 0.079 |
| U | 9.0 | 0.354 |
| U1 | 2.1 | 0.083 |
| W | 0.75±0.15 | $0.030^{+0.006}_{-0.007}$ |
| Z | 0.10 | 0.004 |

13. RECOMMENDED SOLDERING CONDITIONS

The conditions listed below shall be met when soldering the μ PD78P4038.

For details of the recommended soldering conditions, refer to our document **Semiconductor Device Mounting Technology Manual (C10535E)**.

Please consult with our sales offices in case any other soldering process is used, or in case soldering is done under different conditions.

Table 13-1. Soldering Conditions for Surface-Mount Devices (1/2)

(1) μ PD78P4038GC-3B9: 80-pin plastic QFP (14 \times 14 \times 2.7 mm)

| Soldering Process | Soldering Conditions | Symbol |
|------------------------|---|-----------|
| Infrared ray reflow | Peak package's surface temperature: 235°C Reflow time: 30 seconds or less (210°C or more) Maximum allowable number of reflow processes: 3 | IR35-00-3 |
| VPS | Peak package's surface temperature: 215°C Reflow time: 40 seconds or less (200°C or more) Maximum allowable number of reflow processes: 3 | VP15-00-3 |
| Wave soldering | Solder temperature: 260°C or less Flow time: 10 seconds or less Number of flow processes: 1 Preheating temperature : 120°C max. (measured on the package surface) | WS60-00-1 |
| Partial heating method | Terminal temperature: 300°C or less Heat time: 3 seconds or less (for one side of a device) | - |

Caution Do not apply two or more different soldering methods to one chip (except for partial heating method for terminal sections).

(2) μ PD78P4038GC-8BT: 80-pin plastic QFP (14 \times 14 \times 1.4 mm)

| Soldering Process | Soldering Conditions | Symbol |
|------------------------|---|-----------|
| Infrared ray reflow | Peak package's surface temperature: 235°C Reflow time: 30 seconds or less (210°C or more) Maximum allowable number of reflow processes: 2 | IR35-00-2 |
| VPS | Peak package's surface temperature: 215°C Reflow time: 40 seconds or less (200°C or more) Maximum allowable number of reflow processes: 2 | VP15-00-2 |
| Wave soldering | Solder temperature: 260°C or less Flow time: 10 seconds or less Number of flow processes: 1 Preheating temperature : 120°C max. (measured on the package surface) | WS60-00-1 |
| Partial heating method | Terminal temperature: 300°C or less Heat time: 3 seconds or less (for one side of a device) | - |

Caution Do not apply two or more different soldering methods to one chip (except for partial heating method for terminal sections).

Table 13-1. Soldering Conditions for Surface-Mount Devices (2/2)

(3) μ PD78P4038GK-BE9: 80-pin plastic TQFP (fine pitch) (12 × 12 mm)

| Soldering Process | Soldering Conditions | Symbol |
|------------------------|---|------------|
| Infrared ray reflow | Peak package's surface temperature: 235°C Reflow time: 30 seconds or less (210°C or more) Maximum allowable number of reflow processes: 2 Exposure limit: 7 daysNote (10 hours of pre-baking is required at 125°C afterward) <caution> Non-heat-resistant trays, such as magazine and taping trays, cannot be baked before unpacking.</caution> | IR35-107-2 |
| VPS | Peak package's surface temperature: 215°C Reflow time: 40 seconds or less (200°C or more) Maximum allowable number of reflow processes: 2 Exposure limit: 7 daysNote (10 hours of pre-baking is required at 125°C afterward) <caution> Non-heat-resistant trays, such as magazine and taping trays, cannot be baked before unpacking.</caution> | VP15-107-2 |
| Partial heating method | Terminal temperature: 300°C or less Heat time: 3 seconds or less (for one side of a device) | - |

Note Maximum number of days during which the product can be stored at a temperature of 25°C and a relative humidity of 65% or less after dry-pack package is opened.

Caution Do not apply two or more different soldering methods to one chip (except for partial heating method for terminal sections).

APPENDIX A DEVELOPMENT TOOLS

The following development tools are available for system development using the μ PD78P4038. See also (5).

(1) Language processing software

| RA78K4 | Assembler package for all 78K/IV Series models |
|----------|---|
| CC78K4 | C compiler package for all 78K/IV Series models |
| DF784038 | Device file for μPD784038 Subseries models |
| CC78K4-L | C compiler library source file for all 78K/IV Series models |

(2) PROM write tools

| PG-1500 | PROM programmer |
|--------------------|---|
| PA-78P4026GC | Programmer adaptor, connects to PG-1500 |
| PA-78P4038GK | |
| PA-78P4026KK | |
| PG-1500 controller | Control program for PG-1500 |

(3) Debugging tools

• When using the in-circuit emulator IE-78K4-NS

| IE-78K4-NS | In-circuit emulator for all 78K/IV Series models |
|----------------------|--|
| IE-70000-MC-PS-B | Power supply unit for IE-78K4-NS |
| IE-70000-98-IF-C | Interface adapter when the PC-9800 series computer (other than a notebook) is used as the host machine |
| IE-70000-CD-IF | PC card and interface cable when a PC-9800 series notebook is used as the host machine |
| IE-70000-PC-IF-C | Interface adapter when the IBM PC/AT TM or compatible is used as the host machine |
| IE-784038-NS-EM1Note | Emulation board for evaluating μ PD784038 Subseries models |
| NP-80GC | Emulation probe for 80-pin plastic QFP (GC-3B9 and GC-8BT types) |
| NP-80GKNote | Emulation probe for 80-pin plastic TQFP (GK-BE9 type) |
| EV-9200GC-80 | Socket for mounting on target system board made for 80-pin plastic QFP (GC-3B9 and GC-8BT types) |
| TGK-080SDW | Adapter for mounting on target system board made for 80-pin plastic TQFP (fine pitch) (GK-BE9 type) |
| EV-9900 | Tool used to remove the μ PD78P4038KK-T from the EV-9200GC-80 |
| ID78K4-NS | Integrated debugger for IE-78K4-NS |
| SM78K4 | System simulator for all 78K/IV Series models |
| DF784038 | Device file for μPD784038 Subseries models |

Note Under development

• When using the in-circuit emulator IE-784000-R

| IE-784000-R | In-circuit emulator for all 78K/IV Series models |
|---|--|
| IE-70000-98-IF-B IE-70000-98-IF-C | Interface adapter when the PC-9800 series computer (other than a notebook) is used as the host machine |
| IE-70000-98N-IF | Interface adapter and cable when a PC-9800 series notebook is used as the host machine |
| IE-70000-PC-IF-B IE-70000-PC-IF-C | Interface adapter when the IBM PC/AT or compatible is used as the host machine |
| IE-78000-R-SV3 | Interface adapter and cable when the EWS is used as the host machine |
| IE-784038-NS-EM1Note IE-784038-R-EM1 | Emulation board for evaluating μ PD784038 Subseries models |
| IE-78400-R-EM | Emulation board for all 78K/IV Series models |
| IE-78K4-R-EX2Note | Conversion board for 80 pins to use the IE-784038-NS-EM1 on the IE-784000-R. The board is not needed when the conventional product IE-784038-R-EM1 is used. |
| EP-78230GC-R | Emulation probe for 80-pin plastic QFP (GC-3B9 and GC-8BT types) |
| EP-78054GK-R | Emulation probe for 80-pin plastic TQFP (fine pitch) (GK-BE9 type) for all μ PD784038 Subseries |
| EV-9200GC-80 | Socket for mounting on target system board made for 80-pin plastic QFP (GC-3B9 and GC-8BT types) |
| TGK-080SDW | Adapter for mounting on target system board made for 80-pin plastic TQFP (fine pitch) (GK-BE9 type) |
| EV-9900 | Tool used to remove the μ PD78P4038KK-T from the EV-9200GC-80 |
| ID78K4 | Integrated debugger for IE-784000-R |
| SM78K4 | System simulator for all 78K/IV Series models |
| DF784038 | Device file for μPD784038 Subseries models |
| IE-784038-R-EM1 IE-78400-R-EM IE-78K4-R-EX2Note EP-78230GC-R EP-78054GK-R EV-9200GC-80 TGK-080SDW EV-9900 ID78K4 SM78K4 | Emulation board for all 78K/IV Series models Conversion board for 80 pins to use the IE-784038-NS-EM1 on the IE-784000-R. The board is not needed when the conventional product IE-784038-R-EM1 is used. Emulation probe for 80-pin plastic QFP (GC-3B9 and GC-8BT types) Emulation probe for 80-pin plastic TQFP (fine pitch) (GK-BE9 type) for al μPD784038 Subseries Socket for mounting on target system board made for 80-pin plastic QFP (GC-3B9 and GC-8BT types) Adapter for mounting on target system board made for 80-pin plastic TQI (fine pitch) (GK-BE9 type) Tool used to remove the μPD78P4038KK-T from the EV-9200GC-80 Integrated debugger for IE-784000-R System simulator for all 78K/IV Series models |

Note Under development

(4) Real-time OS

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| RX78K/IV | Real-time OS for 78K/IV Series models |
|----------|---------------------------------------|
| MX78K4 | OS for 78K/IV Series models |

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(5) Notes when using development tools

- The ID78K4-NS, ID78K4, and SM78K4 can be used in combination with the DF784038.
- The CC78K4 and RX78K/IV can be used in combination with the RA78K4 and DF784038.
- The NP-80GC is a product from Naito Densei Machida Mfg. Co., Ltd. (044-822-3813). Consult the NEC sales representative for purchasing.
- The TGK-080SDW is a product from TOKYO ELETECH CORPORATION.

Refer to: Daimaru Kogyo, Ltd.

Tokyo Electronic Components Division (03-3820-7112)

Osaka Electronic Components Division (06-244-6672)

· The host machines and operating systems corresponding to each software are shown below.

| Host Machine | PC | EWS |
|--------------------|---|--|
| [OS] | PC-9800 Series [Windows TM] IBM PC/AT and compatibles [Windows] | HP9000 Series 700 TM [HP-UXTM] SPARCstation TM [SunOS TM] NEWS TM (RISC) [NEWS-OS TM] |
| RA78K4 | Note | 0 |
| CC78K4 | Note | 0 |
| PG-1500 controller | Note | - |
| ID78K4-NS | 0 | _ |
| ID78K4 | 0 | 0 |
| SM78K4 | 0 | _ |
| RX78K/IV | Note | 0 |
| MX78K4 | Note | 0 |

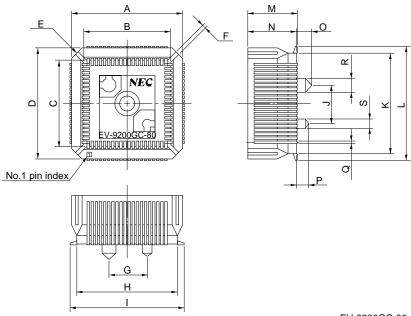
Note Software under MS-DOS

APPENDIX B CONVERSION SOCKET (EV-9200GC-80) AND CONVERSION ADAPTER (TGK-080SDW)

(1) Conversion socket (EV-9200GC-80) package drawings and recommended pattern to mount the socket Connect the μ PD78P4038YKK-T (80-pin ceramic WQFN (14 × 14 mm)) and EP-78230GC-R to the circuit board in combination with the EV-9200GC-80.

Figure B-1. Package Drawings of EV-9200GC-80 (Reference) (unit: mm)

Based on EV-9200GC-80 (1) Package drawing (in mm)

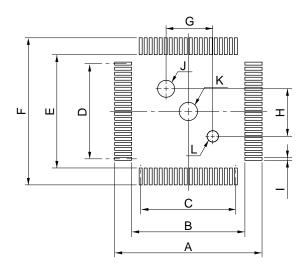


EV-9200GC-80-G0E

| ITEM | MILLIMETERS | INCHES | |
|------|-------------|-----------|--|
| Α | 18.0 | 0.709 | |
| В | 14.4 | 0.567 | |
| С | 14.4 | 0.567 | |
| D | 18.0 | 0.709 | |
| Е | 4-C 2.0 | 4-C 0.079 | |
| F | 0.8 | 0.031 | |
| G | 6.0 | 0.236 | |
| Н | 16.0 | 0.63 | |
| I | 18.7 | 0.736 | |
| J | 6.0 | 0.236 | |
| K | 16.0 | 0.63 | |
| L | 18.7 | 0.736 | |
| М | 8.2 | 0.323 | |
| 0 | 8.0 | 0.315 | |
| N | 2.5 | 0.098 | |
| Р | 2.0 | 0.079 | |
| Q | 0.35 | 0.014 | |
| R | φ2.3 | φ0.091 | |
| S | 1.5 | 0.059 | |

Figure B-2. Recommended Pattern to Mount EV-9200GC-80 on a Substrate (Reference) (unit: mm)

Based on EV-9200GC-80 (2) Pad drawing (in mm)



EV-9200GC-80-P1E

| ITEM | MILLIMETERS | INCHES | |
|------|------------------------------------|--|--|
| Α | 19.7 | 0.776 | |
| В | 15.0 | 0.591 | |
| С | 0.65±0.02 × 19=12.35±0.05 | $0.026^{+0.001}_{-0.002} \times 0.748 = 0.486^{+0.003}_{-0.002}$ | |
| D | $0.65\pm0.02\times19=12.35\pm0.05$ | $0.026^{+0.001}_{-0.002}$ $0.748=0.486^{+0.003}_{-0.002}$ | |
| Е | 15.0 | 0.591 | |
| F | 19.7 | 0.776 | |
| G | 6.0±0.05 | $0.236^{+0.003}_{-0.002}$ | |
| Н | 6.0±0.05 | $0.236^{+0.003}_{-0.002}$ | |
| I | 0.35±0.02 | 0.014 ^{+0.001} _{-0.001} | |
| J | φ2.36±0.03 | φ0.093 ^{+0.001} _{-0.002} | |
| K | φ2.3 | φ0.091 | |
| L | φ1.57±0.03 | φ0.062 ^{+0.001} _{-0.002} | |

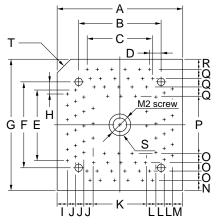
Dimensions of mount pad for EV-9200 and that for target device (QFP) may be different in some parts. For the recommended mount pad dimensions for QFP, refer to "SEMICONDUCTOR DEVICE MOUNTING TECHNOLOGY MANUAL" (C10535E).

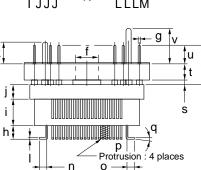
(2) Conversion adapter (TGK-080SDW) package drawings

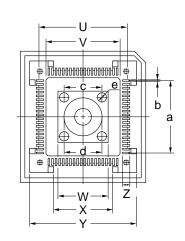
Connect the μ PD78P4038GK-BE9 (80-pin plastic TQFP (fine pitch: 12 \times 12 mm)) to the circuit board in combination with the TGK-080SDW.

Figure B-3. Package Drawings of TGK-080SDW (Reference) (unit: mm)

TGK-080SDW (TQPACK080SD + TQSOCKET080SDW) Package dimension (unit: mm)







| ITEM | MILLIMETERS | INCHES | ITEM | MILLIMETERS | INCHES |
|------|-------------|-------------------|------|------------------|-------------------------|
| Α | 18.0 | 0.709 | а | 0.5x19=9.5±0.10 | 0.020x0.748=0.374±0.004 |
| В | 11.77 | 0.463 | b | 0.25 | 0.010 |
| С | 0.5x19=9.5 | 0.020x0.748=0.374 | С | ϕ 5.3 | φ0.209 |
| D | 0.5 | 0.020 | d | φ5.3 | φ0.209 |
| E | 0.5x19=9.5 | 0.020x0.748=0.374 | е | φ1.3 | φ0.051 |
| F | 11.77 | 0.463 | f | φ3.55 | φ0.140 |
| G | 18.0 | 0.709 | g | ϕ 0.3 | φ0.012 |
| Н | 0.5 | 0.020 | h | 1.85±0.2 | 0.073±0.008 |
| T | 1.58 | 0.062 | i | 3.5 | 0.138 |
| J | 1.2 | 0.047 | j | 2.0 | 0.079 |
| K | 7.64 | 0.301 | k | 3.0 | 0.118 |
| L | 1.2 | 0.047 | T | 0.25 | 0.010 |
| М | 1.58 | 0.062 | m | 14.0 | 0.551 |
| N | 1.58 | 0.062 | n | 1.4±0.2 | 0.055±0.008 |
| 0 | 1.2 | 0.047 | 0 | 1.4±0.2 | 0.055±0.008 |
| Р | 7.64 | 0.301 | р | h=1.8 ϕ 1.3 | h=0.071 ϕ 0.051 |
| Q | 1.2 | 0.047 | q | 0~5° | 0.000~0.197° |
| R | 1.58 | 0.062 | r | 5.9 | 0.232 |
| S | ϕ 3.55 | φ0.140 | s | 0.8 | 0.031 |
| Т | C 2.0 | C 0.079 | t | 2.4 | 0.094 |
| U | 12.31 | 0.485 | u | 2.7 | 0.106 |
| V | 10.17 | 0.400 | v | 3.9 | 0.154 |
| W | 6.8 | 0.268 | | ٦ | GK-080SDW-G1E |
| X | 8.24 | 0.324 | | | |
| Y | 14.8 | 0.583 | | | |
| Z | 1.4±0.2 | 0.055±0.008 | | | |

note: Product by TOKYO ELETECH CORPORATION.

APPENDIX C RELATED DOCUMENTS

Documents Related to Devices

| Document Name | Document No. | |
|---|--------------|----------|
| | English | Japanese |
| μPD784031 Data Sheet | U11507E | U11507J |
| μPD784035, 784036, 784037, 784038 Data Sheet | U10847E | U10847J |
| μPD78P4038 Data Sheet | This manual | U10848J |
| μPD784038, 784038Y Sub-Series User's Manual, Hardware | U11316E | U11316J |
| μPD784038 Sub-Series Special Function Registers | - | U11090J |
| 78K/IV Series User's Manual, Instruction | U10905E | U10905J |
| 78K/IV Series Instruction Summary Sheet | - | U10594J |
| 78K/IV Series Instruction Set | - | U10595J |
| 78K/IV Series Application Note, Software Basic | - | U10095J |

Documents Related to Development Tools (User's Manual)

| Document Name | | Document No. | |
|---|---|---------------|---------------|
| | | English | Japanese |
| RA78K4 Assembler Package | Operation | U11334E | U11334J |
| | Language | U11162E | U11162J |
| RA78K Series Structured Assembler Preprocessor | | U11743E | U11743J |
| CC78K4 Series | Operation | U11572E | U11572J |
| | Language | U11571E | U11571J |
| CC78K Series Library Source File | | U12322E | U12322J |
| PG-1500 PROM Programmer | | U11940E | U11940J |
| PG-1500 Controller PC-9800 Series (MS-DOS TM) Base | | EEU-1291 | EEU-704 |
| PG-1500 Controller IBM PC Series (PC DOS TM) Base | | U10540E | EEU-5008 |
| IE-78K4-NS | IE-78K4-NS | | U13356J |
| IE-784000-R | | EEU-1534 | U12903J |
| IE-784038-NS-EM1 | | To be created | To be created |
| IE-784038-R-EM1 | | U11383E | U11383J |
| EP-78230 | EP-78230 | | EEU-985 |
| EP-78054GK-R | EP-78054GK-R | | EEU-932 |
| SM78K4 System Simulator Windows Base | 3K4 System Simulator Windows Base Reference | | U10093J |
| SM78K Series System Simulator | Series System Simulator External Parts User Open Interface Specifications | | U10092J |
| D78K4-NS Integrated Debugger Reference | | U12796E | U12796J |
| D78K4 Integrated Debugger Windows Base Reference | | U10440E | U10440J |
| ID78K4 Integrated Debugger HP-UX, SunOS, NEWS-OS Base Reference | | U11960E | U11960J |

Caution The above documents may be revised without notice. Use the latest versions when you design application systems.

Documents Related to Software to Be Incorporated into the Product (User's Manual)

| Document Name | | Document No. | |
|-----------------------------|--------------|--------------|----------|
| | | English | Japanese |
| 78K/IV Series Real-Time OS | Basic | U10603E | U10603J |
| | Installation | U10604E | U10604J |
| | Debugger | - | U10364J |
| OS for 78K/IV Series MX78K4 | Basic | - | U11779J |

* Other Documents

| Document Name | Document No. | |
|--|--------------|----------|
| | English | Japanese |
| IC PACKAGE MANUAL | C10943X | |
| Semiconductor Device Mounting Technology Manual | C10535E | C10535J |
| Quality Grades on NEC Semiconductor Device | C11531E | C11531J |
| NEC Semiconductor Device Reliability/Quality Control System | C10983E | C10983J |
| Guide to Prevent Damage for Semiconductor Devices by Electrostatic Discharge (ESD) | C11892E | C11892J |
| Semiconductor Device Quality Control/Reliability Handbook | _ | C12769J |
| Guide for Products Related to Microcomputer: Other Companies | - | U11416J |

Caution The above documents may be revised without notice. Use the latest versions when you design application systems.

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NOTES FOR CMOS DEVICES —

1 PRECAUTION AGAINST ESD FOR SEMICONDUCTORS

Note: Strong electric field, when exposed to a MOS device, can cause destruction of the gate oxide and ultimately degrade the device operation. Steps must be taken to stop generation of static electricity as much as possible, and quickly dissipate it once, when it has occurred. Environmental control must be adequate. When it is dry, humidifier should be used. It is recommended to avoid using insulators that easily build static electricity. Semiconductor devices must be stored and transported in an anti-static container, static shielding bag or conductive material. All test and measurement tools including work bench and floor should be grounded. The operator should be grounded using wrist strap. Semiconductor devices must not be touched with bare hands. Similar precautions need to be taken for PW boards with semiconductor devices on it.

(2) HANDLING OF UNUSED INPUT PINS FOR CMOS

Note: No connection for CMOS device inputs can be cause of malfunction. If no connection is provided to the input pins, it is possible that an internal input level may be generated due to noise, etc., hence causing malfunction. CMOS device behave differently than Bipolar or NMOS devices. Input levels of CMOS devices must be fixed high or low by using a pull-up or pull-down circuitry. Each unused pin should be connected to VDD or GND with a resistor, if it is considered to have a possibility of being an output pin. All handling related to the unused pins must be judged device by device and related specifications governing the devices.

(3) STATUS BEFORE INITIALIZATION OF MOS DEVICES

Note: Power-on does not necessarily define initial status of MOS device. Production process of MOS does not define the initial operation status of the device. Immediately after the power source is turned ON, the devices with reset function have not yet been initialized. Hence, power-on does not guarantee out-pin levels, I/O settings or contents of registers. Device is not initialized until the reset signal is received. Reset operation must be executed immediately after power-on for devices having reset function.

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